

Reliability Issues

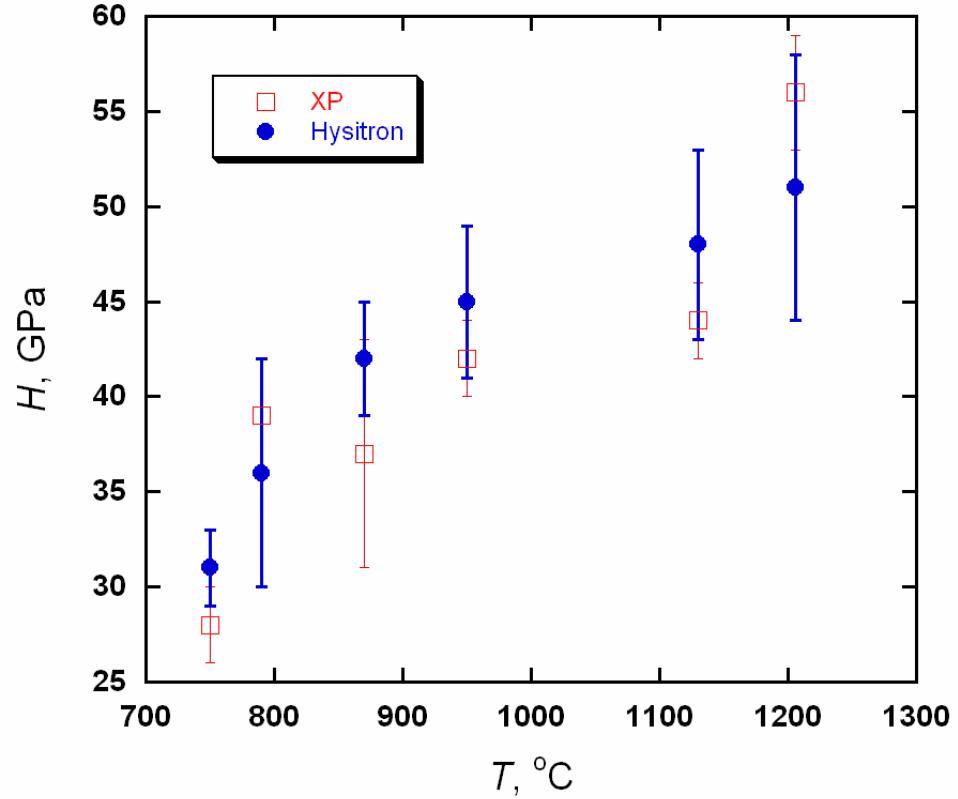
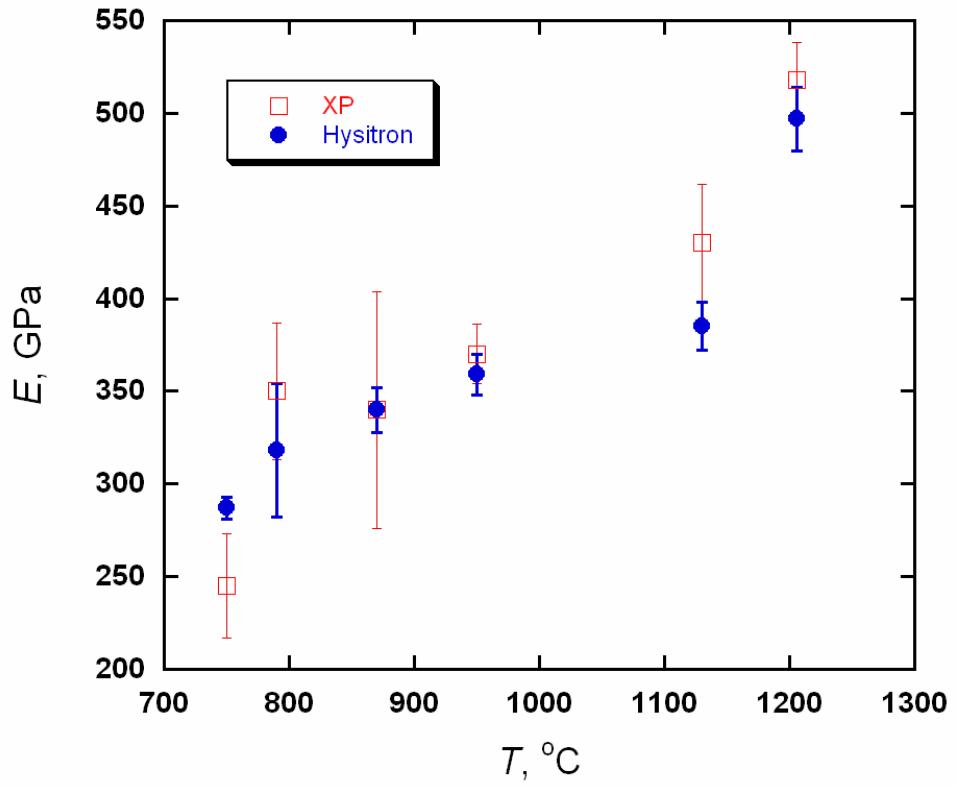
W.W. Gerberich, W.M. Mook, M.J. Cordill,
and J.M. Jungk

Chemical Engineering and Materials Science
University of Minnesota

- State-of-the-Art
- Current Areas of Investigation
- Barriers to Accurate Measurement (or understanding)
 - Size Effect
 - Yield Points
 - Adhesion
 - Work Hardening
- Road Map

State-of-the-Art Measurements

Thermal Plasma CVD SiC



Error bars = 1σ

MTS XP Continuous Stiffness ~ average of 3-5 runs (500 pts. Each)
Hysitron TriboIndenter ~ average of 12 runs

From Fall 2004 MRS

Symposia R: Nanoindentation and Nanomechanics
V: Size Effects in Plasticity

What are the hot topics addressing:
“Mechanical Behavior Aspects in Design at the Nanoscale”?

- | | | |
|-------------------------------|---|------------------------------------|
| S: Size Effects | : | 32 papers |
| T: Temp. or Viscoelasticity | : | 15 papers (also highlighted at the |
| M: Multiscale Modeling | : | 14 papers Nanomechanics |
| A: Adhesion or Surface Energy | : | 11 papers Workshop in Asilomar) |

What Barriers do these represent to accurate nanoscale measures?

S: Size Effects; T: Temperature or Viscoelasticity; A: Adhesion or Surface Energy

Polymers	Metals & Semiconductors	Ceramics
$S(\gamma_s, W_A, p_o) \rightarrow E, \sigma_{ys}, K_{IC}$	$S(\gamma_s, \perp, \Sigma\perp, p_o) \rightarrow E, \sigma_{ys}, K_{IC}$	$S(?)$
$T(W_A, t_c) \rightarrow E, \sigma_{ys}, K_{IC}, da/dt$	$T(\perp, \Sigma\perp, t_c) \rightarrow \sigma_{ys}, K_{IC}, da/dt$	$T(\perp, t_c) \rightarrow K_{IC}, da/dt$
$\Delta T(\text{drift}) \rightarrow (\text{all})$	$\Delta T(\text{drift}) \rightarrow (\text{all})$	$\Delta T(\text{drift}) \rightarrow (\text{all})$

Nomenclature: Properties

E, σ_{ys}, K_{IC} are relatively time-independent

da/dt represents time dependent creep, fatigue, stress corrosion

Fundamental Variables

γ_s – surface energy;

W_A – work of adhesion

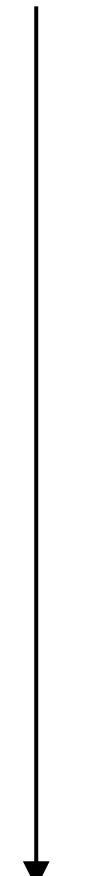
p_o – pressure;

\perp - dislocation nucleation or image force

$\Sigma\perp$ - work hardening or strain gradient plasticity

t_c – characteristic time for diffusion, cross-slip, corrosion

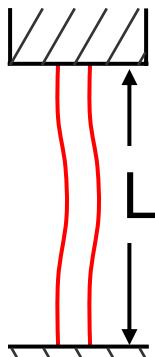
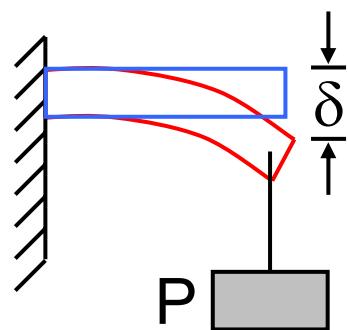
Challenges: Small Length Scales

- Importance
 - Indentation Size Effect
 - Metals
 - Polymers?
 - Film Fracture
 - Nanoparticles
- 
- top
down*

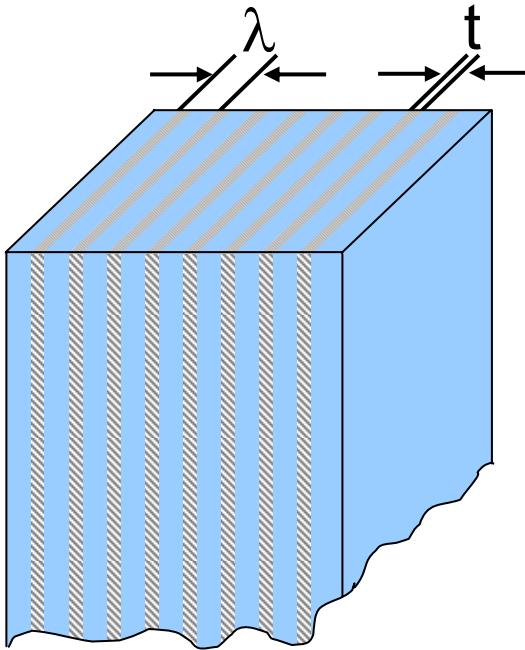
Length Scales for Property Prediction

Rigidity

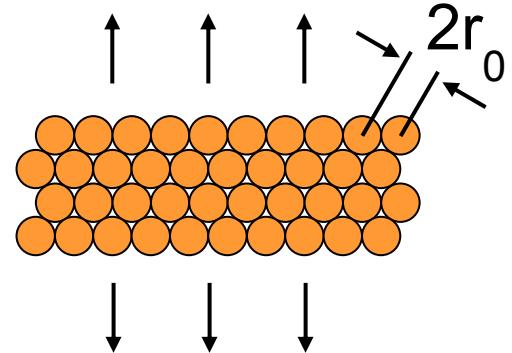
Macro



Micro



Atomistic



$$P \sim \alpha_i \left(\frac{\delta}{L^3} \right) \sim \alpha_i \left(\frac{1}{L^2} \right)$$

α_i has $N \cdot m^2$ units

$$\sim \alpha_i \left(\frac{1}{\lambda \cdot L} \right)$$

λ = laminate spacing

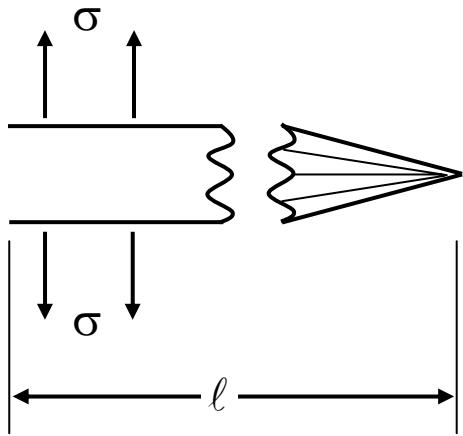
$$\sim \alpha_i \left(\frac{A}{r_0^4} \right) \cdot \left(\frac{\delta}{L} \right)$$

A = cross – section

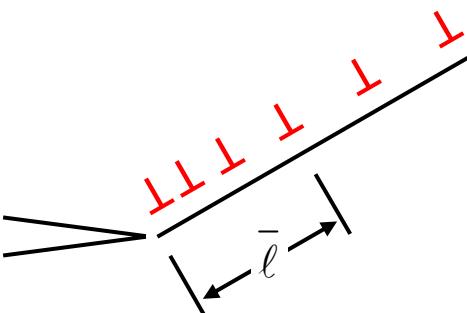
Length Scales for Property Prediction

Fracture Energy, G

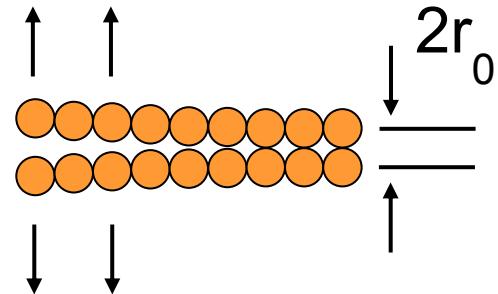
Macro



Micro



Atomistic



$$G \approx \frac{\sigma^2 \ell}{E}$$

ℓ = crack

E = modulus

$$\sim \frac{Eb^2}{\bar{\ell}}$$

λ = average dislocation
spacing

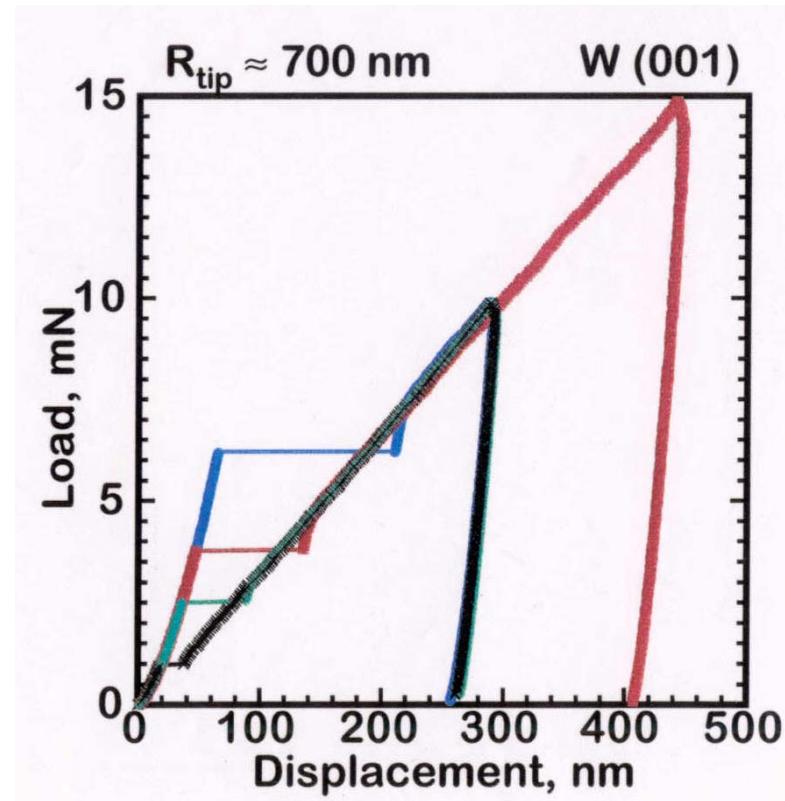
$$\sim 2\gamma_s \sim \frac{a_i}{r_0^3}$$

γ_s = surface energy

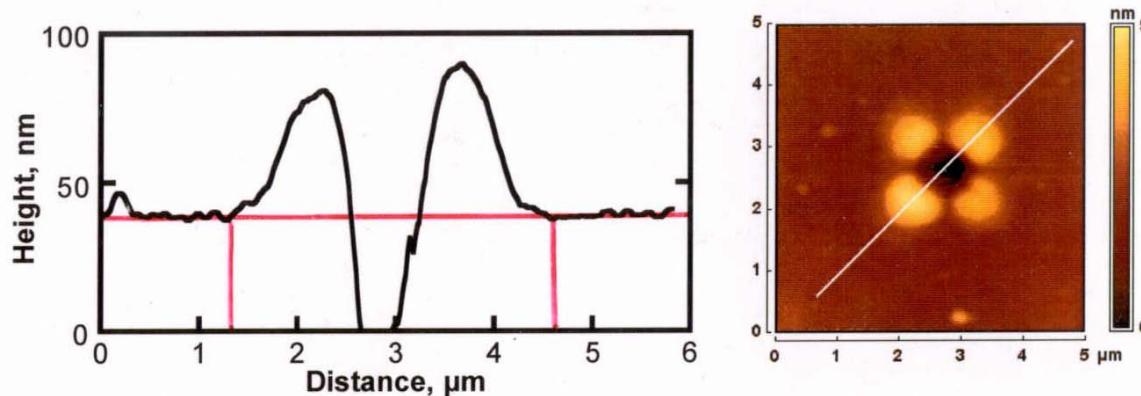
r_0 = atomic radius

Single Crystal Indentation : Master Curve

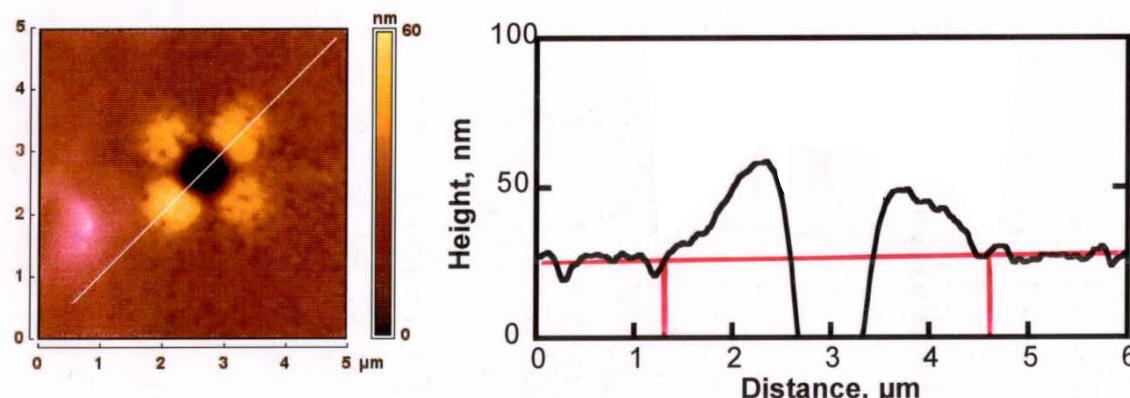
- Excursion displacement scales with critical load.
 - Initial displacement follows from elastic Hertzian contact
 - Final displacement determined by elastic/plastic master curve



Plastic Zone Around $<100>$ Fe-3%Si Before and After Thermal Oxide Treatment

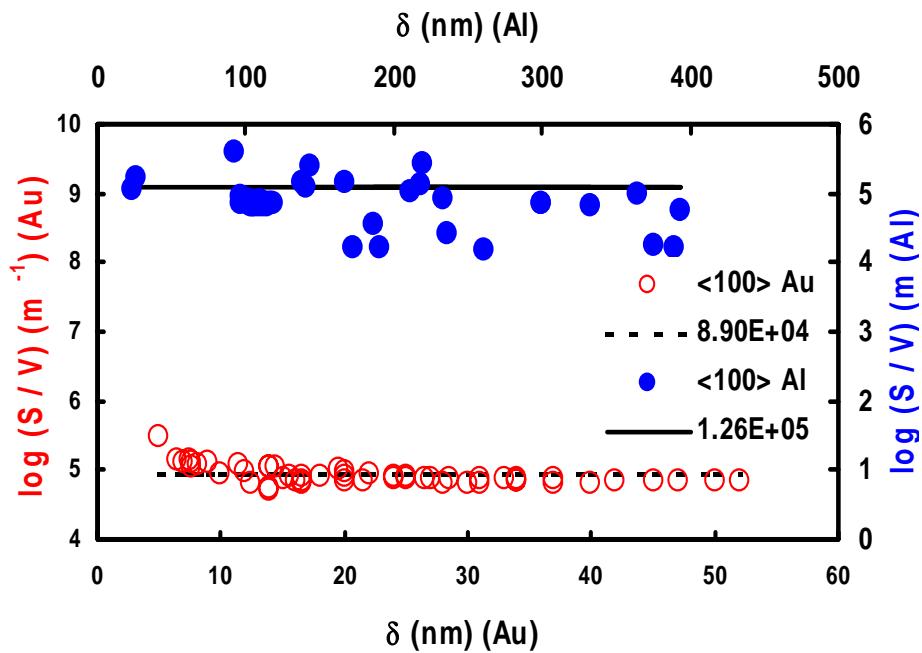
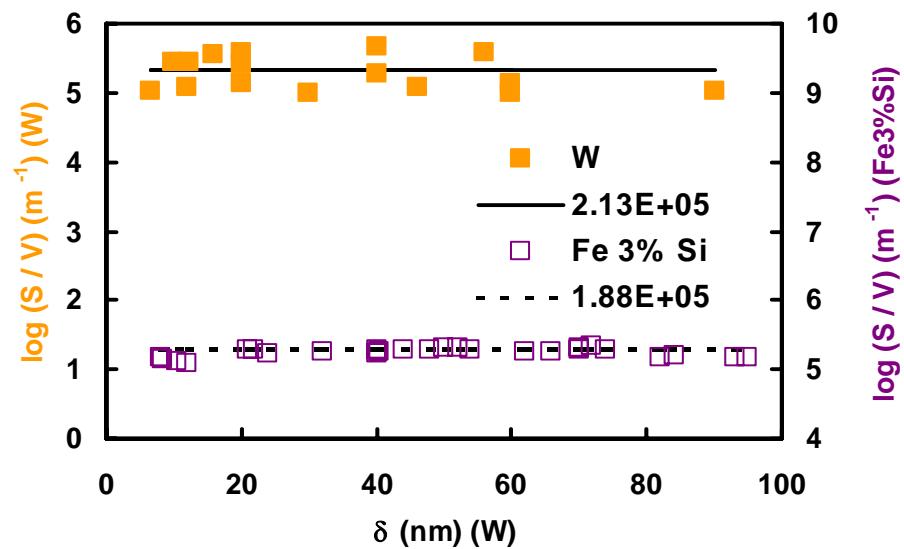


Before Oxide Treatment



After Oxide Treatment

Volume-to-Surface Ratio as a Length Scale



Continuum Pile-up

$$(1) \quad h(r) \approx (1-\nu) \frac{\sigma_{ys}}{E} \left[\frac{c^3}{r^3} \right] \left[\frac{\pi r}{2} \right]$$

$h(r)$ = height as a function of distance
 σ_{ys}/E = yield to modulus ratio
 c = plastic zone radius

$$(2) \quad h(r=a) \approx nb$$

where n \perp 's are released to form pile up from (1) + (2)

$$(3) \quad n_{CR} = \frac{\pi(1-\nu)\sigma_{ys}}{2bE} \cdot \frac{c^3}{a^2}$$

since $\ell_s = V/S = 2c^3/3a^2$, (3) becomes

$$(4) \quad n_{CR} = \frac{3\pi\ell_s(1-\nu)\tau_{ys}}{4b\mu}$$

$$\frac{\tau_{ys}}{\mu} \sim \frac{\sigma_{ys}}{E}$$

-----Eshelby (1951) -----

$$(5) \quad n_{pile-up} = \frac{\pi\ell_s(1-\nu)\tau_{ys}}{2b\mu}$$

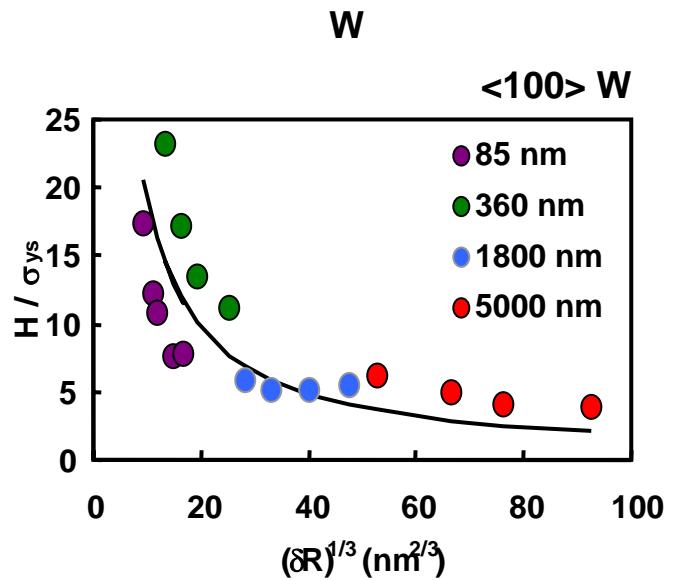
ISE – Volume-to-Surface Ratio

Observed a relationship between the volume of deformation and generated surface area

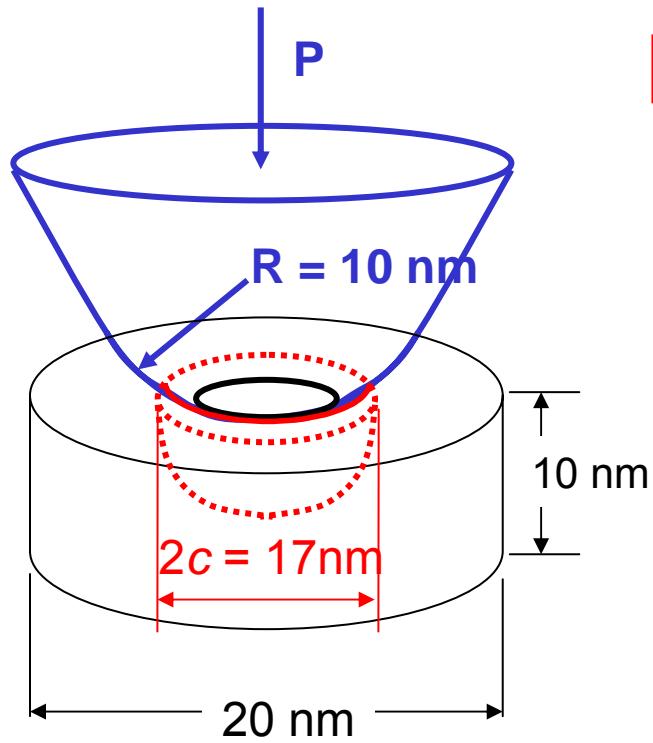
Combined with plastic zone model

$$H = \sigma_{ys} \left(\frac{V}{S} \right)^{2/3} \frac{1}{(3\delta R)^{1/3}}$$

$$\frac{V}{S} \longrightarrow \text{length scale}$$



Consider a Cu Feature {Boundary Constraint}



Assume: 1 nanodot = 10 nm thick, 20 nm diameter

$$\sigma_{ys}^{cu} \sim 1.4 \text{ GPa}$$

$$\delta \sim 1 \text{ nm}$$

$$R \sim 10 \text{ nm}$$

$$a \sim 4 \text{ nm}$$

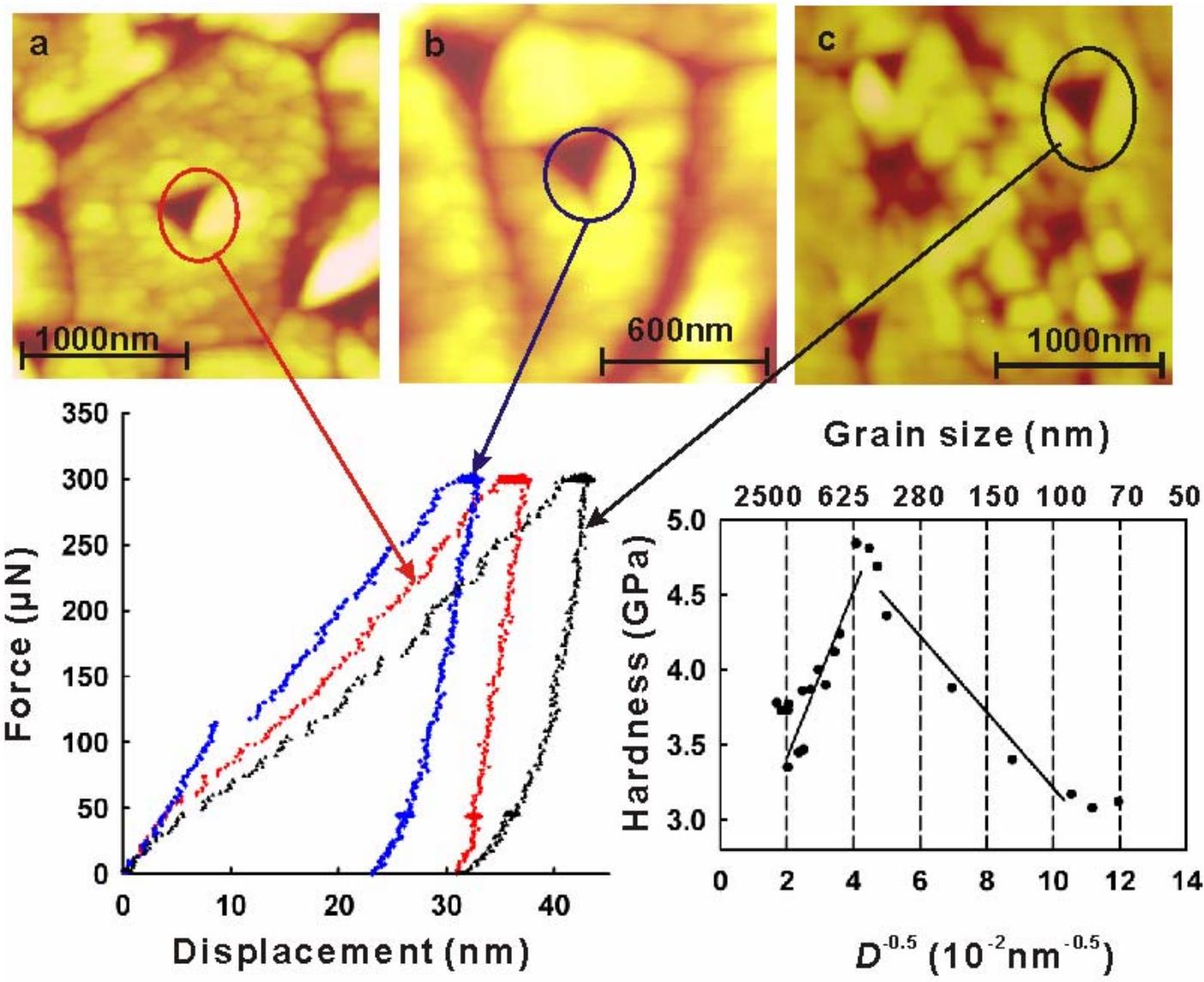
$$P = 4.2 \text{ GPa} \{5 \times 10^{-17} \text{ m}^2\} = 210 \text{ nN}$$

(H)

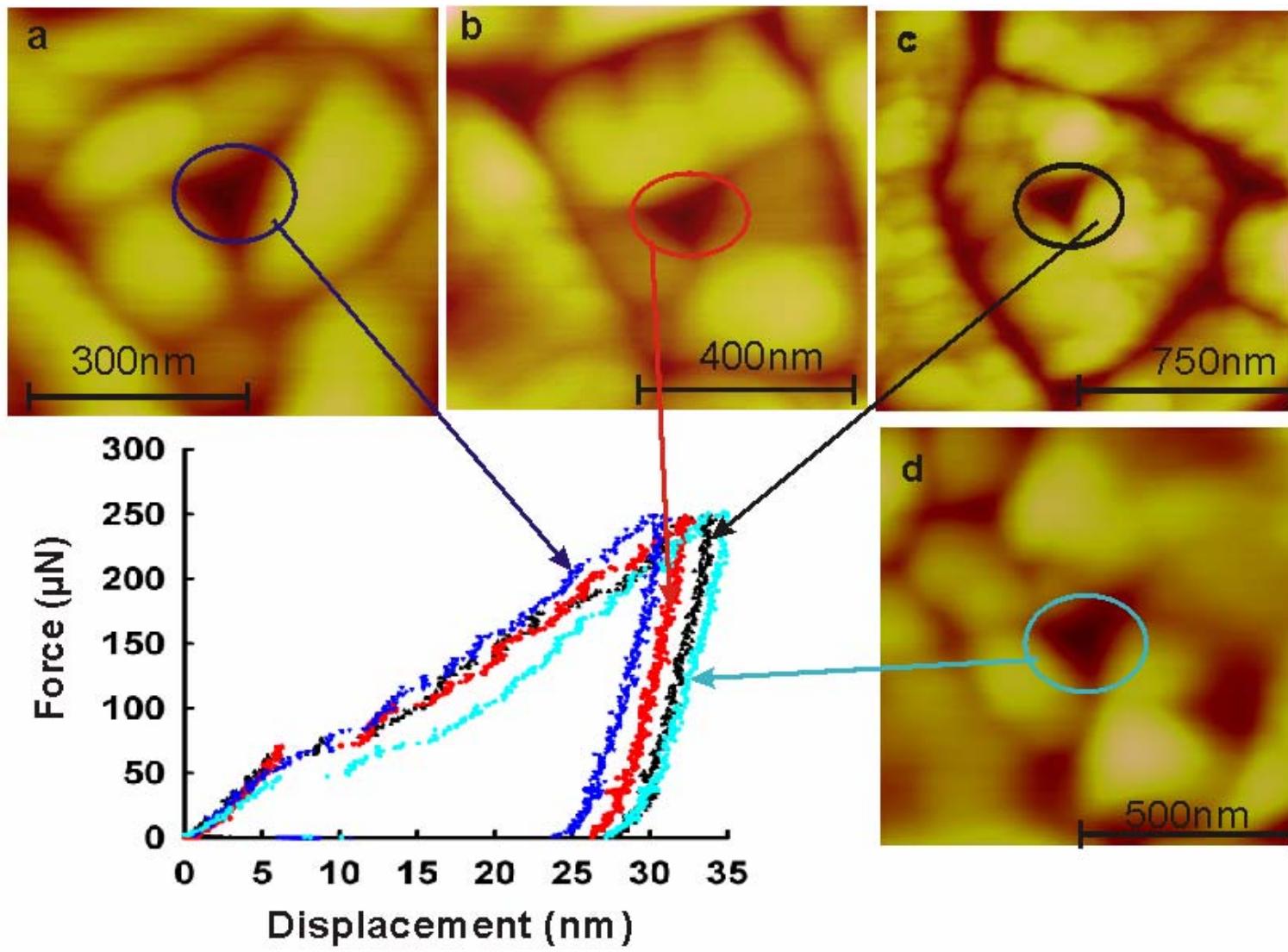
If (??) continuum, plastic zone, c

$$c \sim \sqrt{\frac{3P}{2\pi\sigma_{ys}}} = 8.5 \text{ nm}$$

Note $c = 2.12a$



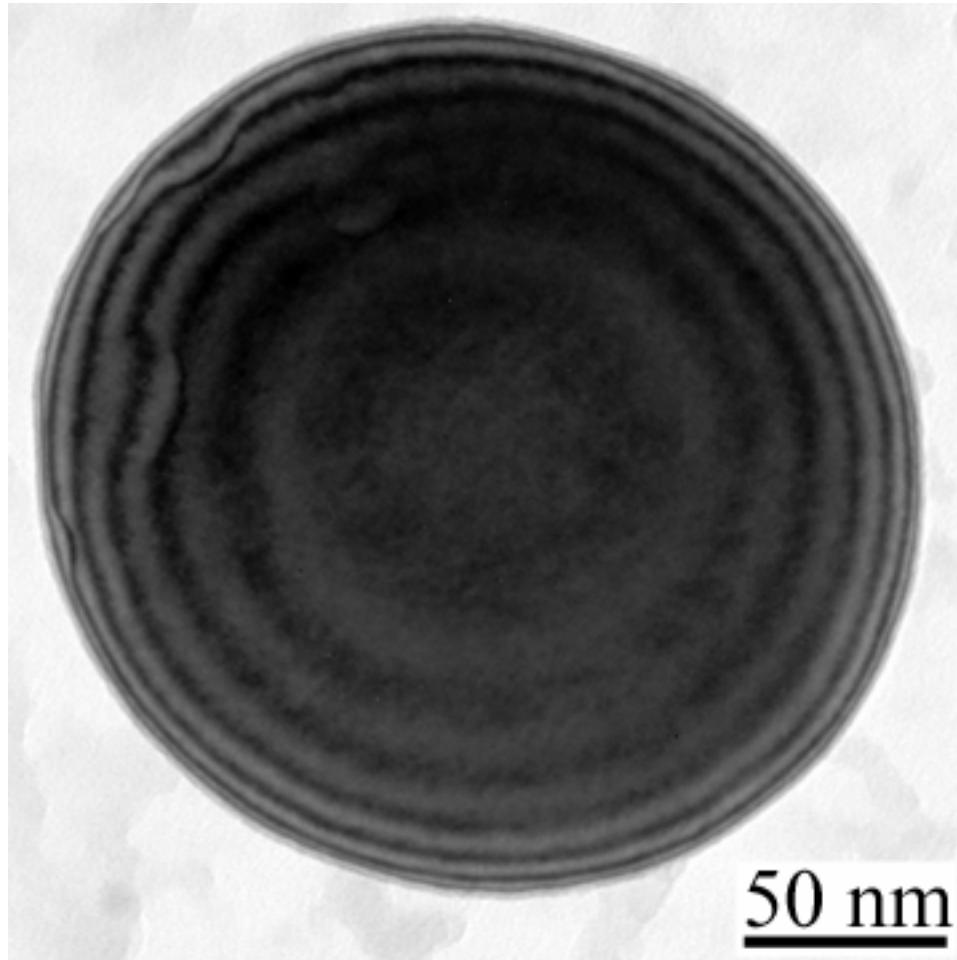
Nanoindentation with peak force 300 μN



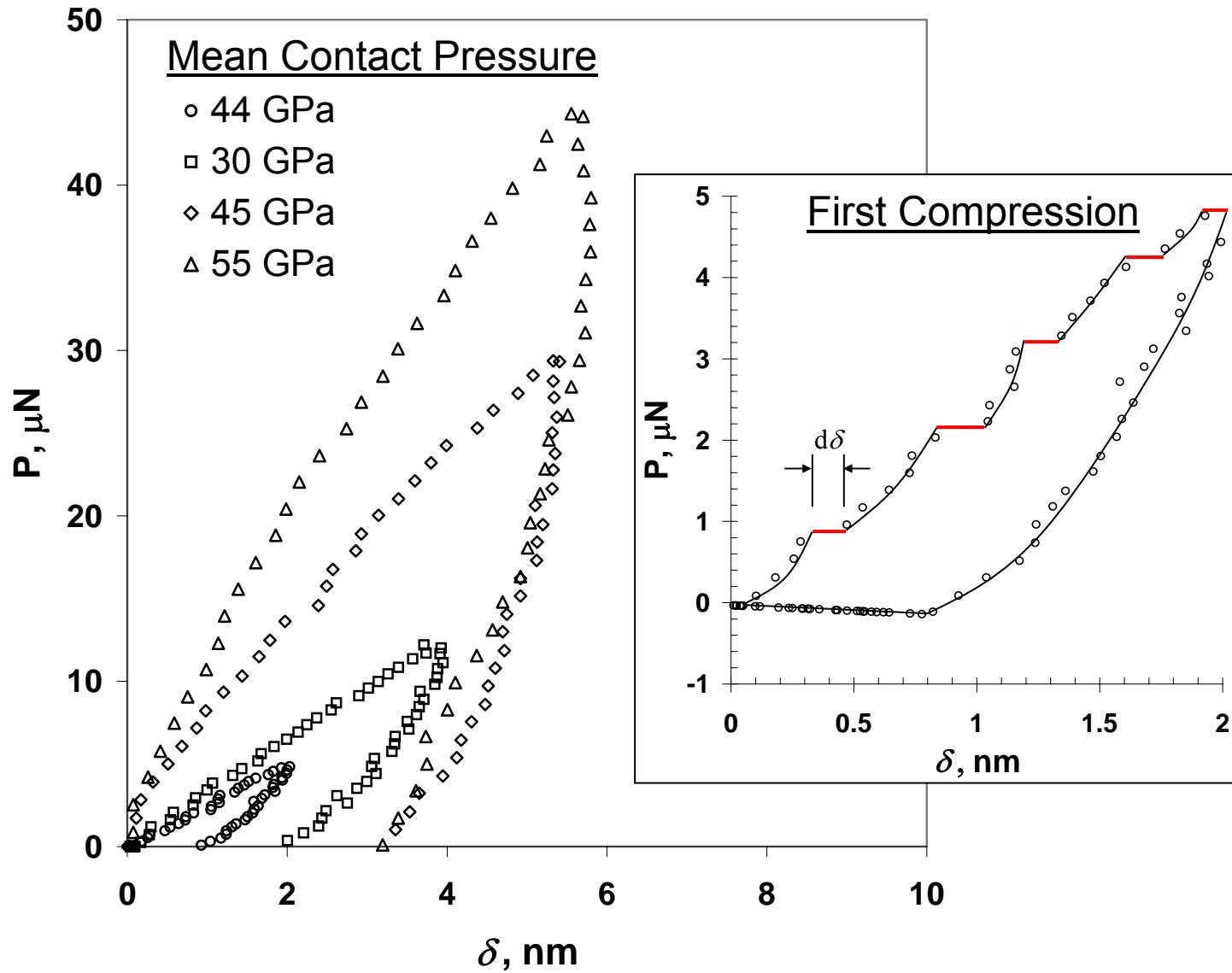
Nanoindentation with peak force 250 μN

Silicon Nanoparticles

TEM of non-equilibrium particle

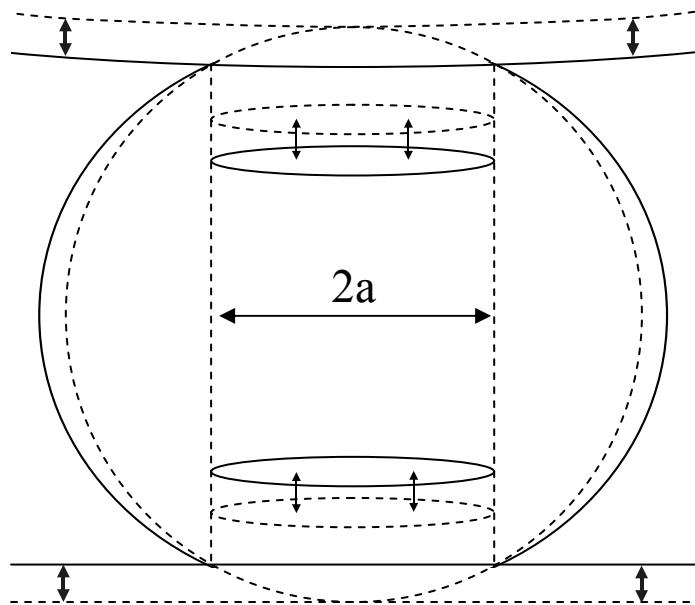


Silicon nanoparticle: 39 nm diameter



Idealized Compression of a Nanosphere

$$\ell_s = \frac{\frac{4}{3}\pi r^2}{2\pi a^2} = \frac{2r^3}{3a^2}$$



Equilibrium Arrest Position

Zhou and Thomson's Analysis for a Plastically Polarizable Material (Crack Problem → Indent)

$$\sigma_f = \frac{p_o}{2} \left[\frac{1+\nu}{1 - \frac{z_i}{a} \tan^{-1} \left(\frac{a}{z_i} \right) + \frac{1}{2} \left(1 + \frac{z_i^2}{a^2} \right)} - \frac{a^2}{a^2 + z_i^2} \right] - \frac{\mu b_i}{4\pi(1-\nu)z_i} + \sum_{j \neq i} \frac{\mu b_j}{2\pi(1-\nu)} \frac{1}{z_i - z_j}$$

σ_f = friction stress at arrest

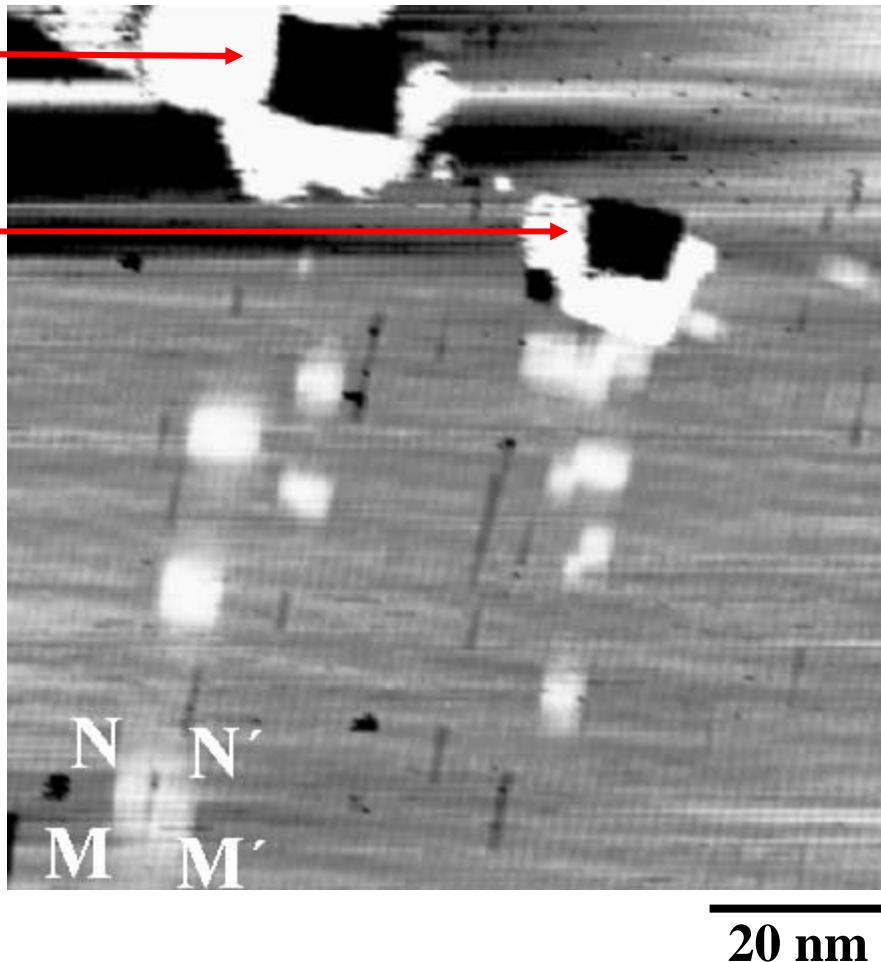
p_o = maximum pressure = $\frac{3P}{2\pi a^2}$

z = distance below contact

a = contact radius

STM image of nanoindentations in the Au(001) surface

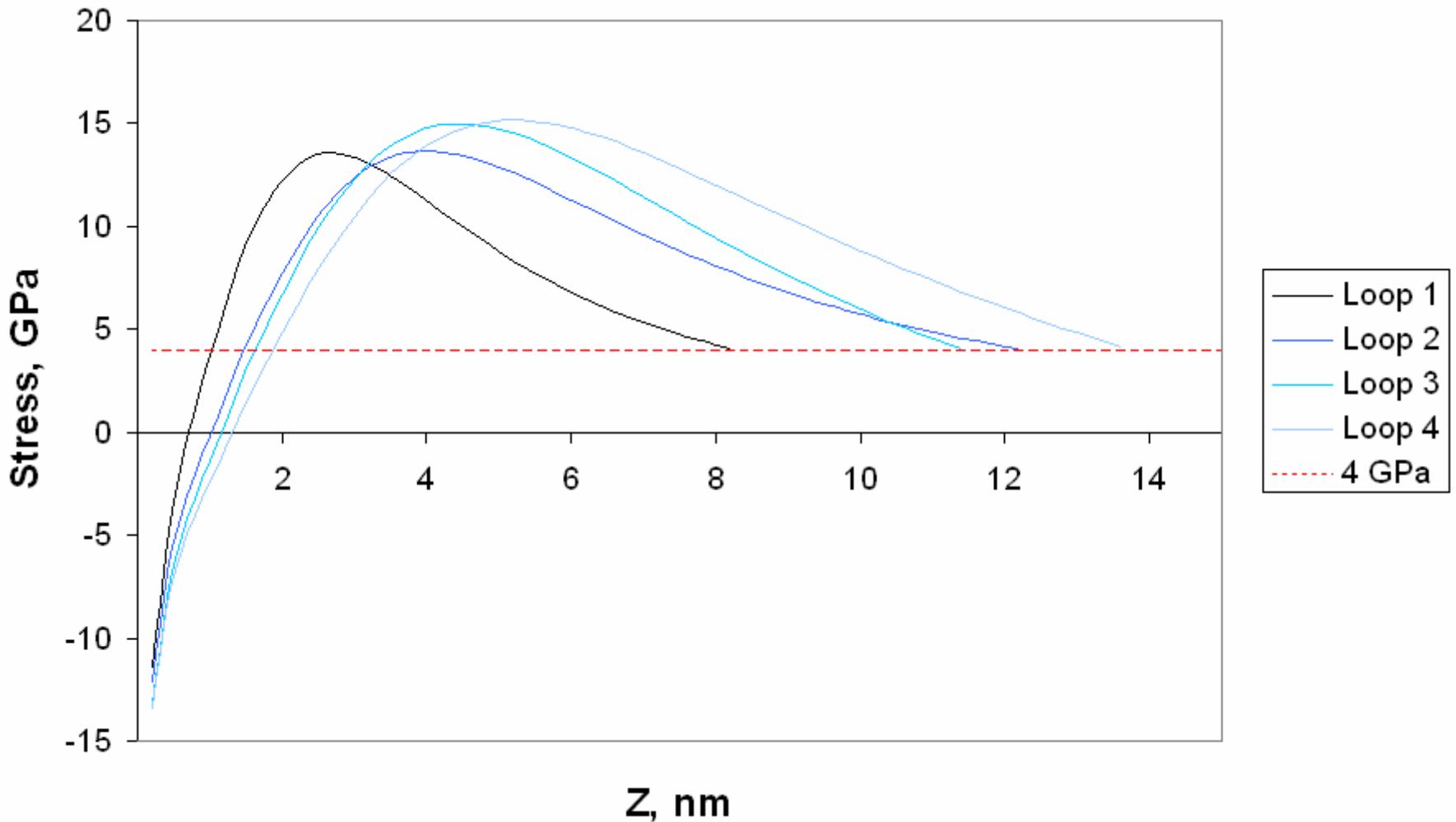
Indents



Rows of hillocks stemming from the nanoindentation points and following a $<110>$ direction are visible.

Silicon nanoparticle: 39 nm diameter

Dislocation Glide Depth



Work to move a dislocation below the surface for a sphere of Silicon

1st Excursion: $P = 0.92 \text{ } \mu\text{N}$, $\delta_{before} = 0.26 \text{ nm}$, $\delta_{after} = 0.41 \text{ nm}$

$$W_E = Pd\delta = \boxed{1.43 \times 10^{-16} \text{ N}\cdot\text{m}} = \Delta S + \Delta W_{\perp} + \Delta U_{\perp}$$

Surface Work: $a_{before} = 2.22 \text{ nm}$, $a_{after} = 2.81 \text{ nm}$

$$\Delta S = \gamma_s A_{after} - \gamma_s A_{before} = 2.91 \times 10^{-17} \text{ N}\cdot\text{m}$$

Dislocation Work: $\Delta W_{\perp} = \tau_{ys} b \cdot 2\pi a \cdot x = 10.5 \times 10^{-17} \text{ N}\cdot\text{m}$

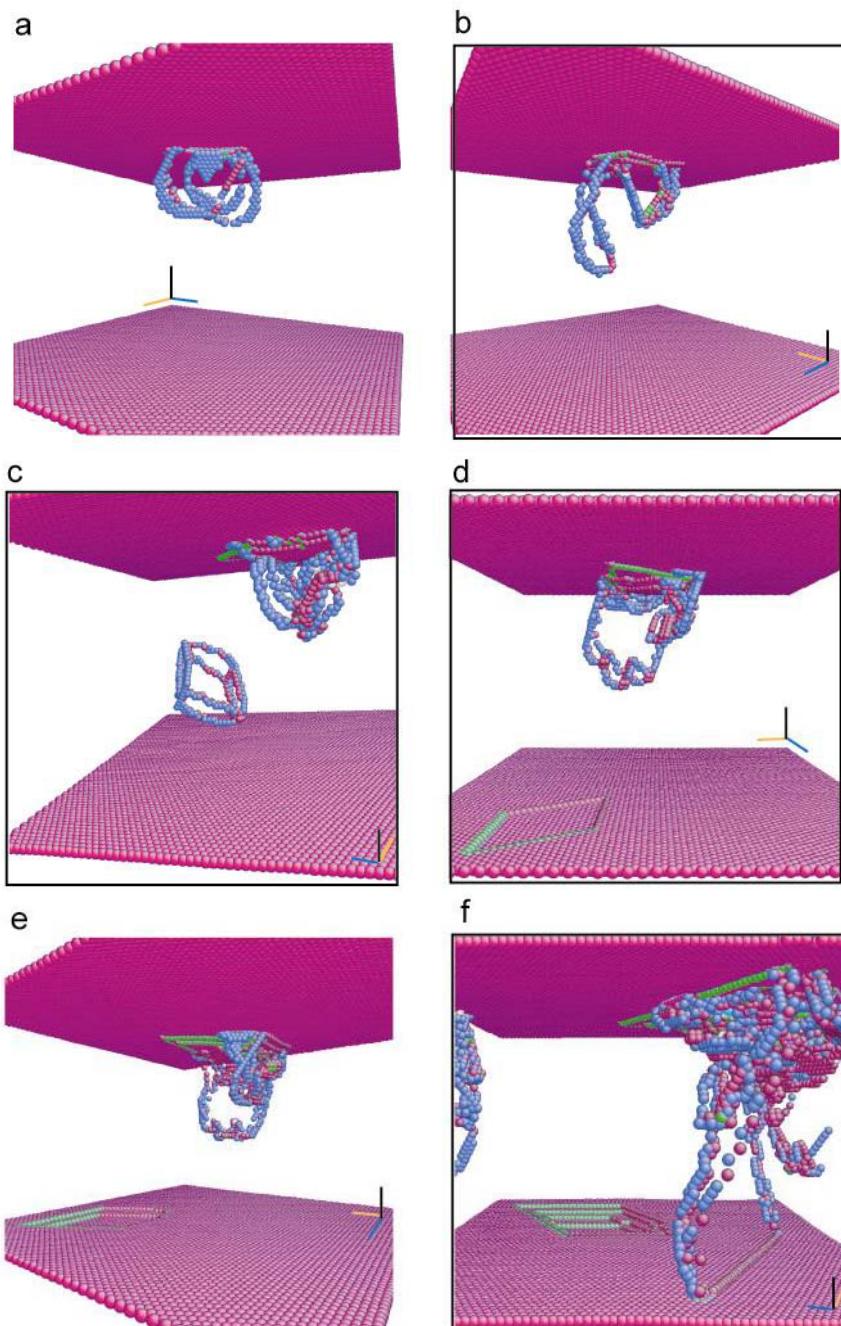
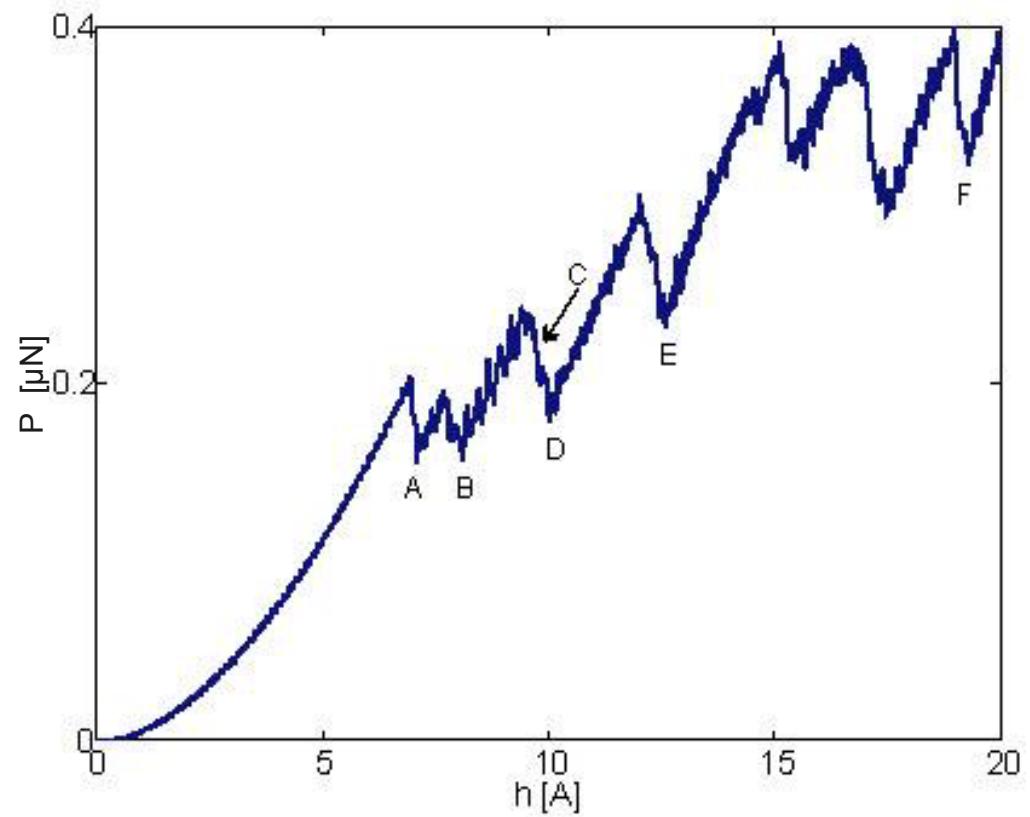
Stored Elastic Energy: $\Delta U_{\perp} = \pi a \left[1 + \frac{1}{1-\nu} \right] \left[\frac{\mu b^2}{4\pi} \ln \frac{ae^2}{b} \right] = 2.65 \times 10^{-17} \text{ N}\cdot\text{m}$

113% Accounted for

$$= \boxed{1.61 \times 10^{-16} \text{ N}\cdot\text{m}}$$

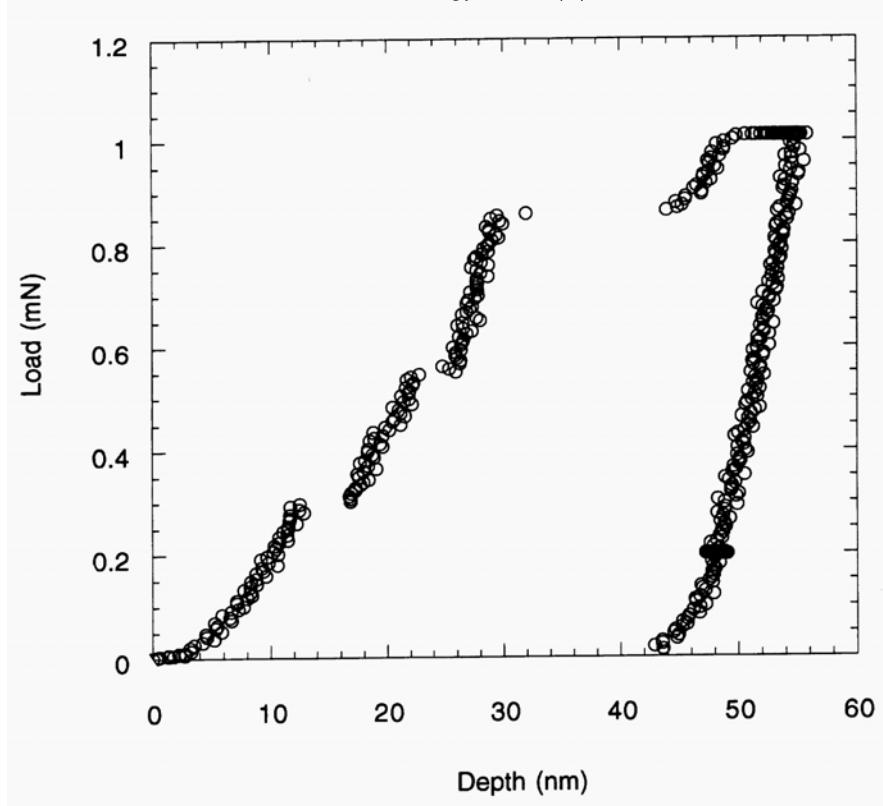
4 such excursions : $93 \pm 20\%$

Courtesy, S. Yip, K van Vliet, MIT

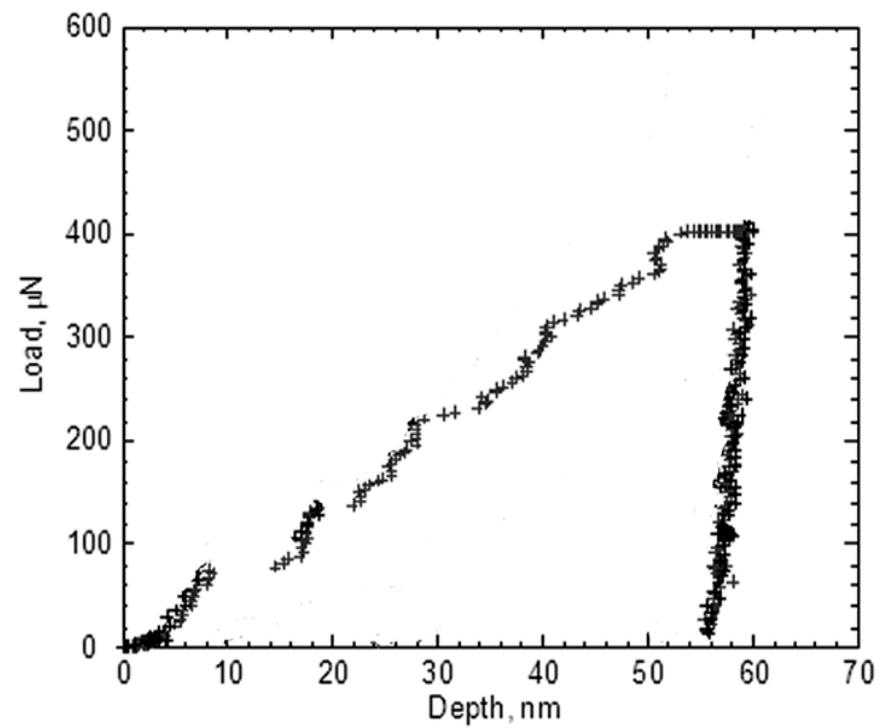


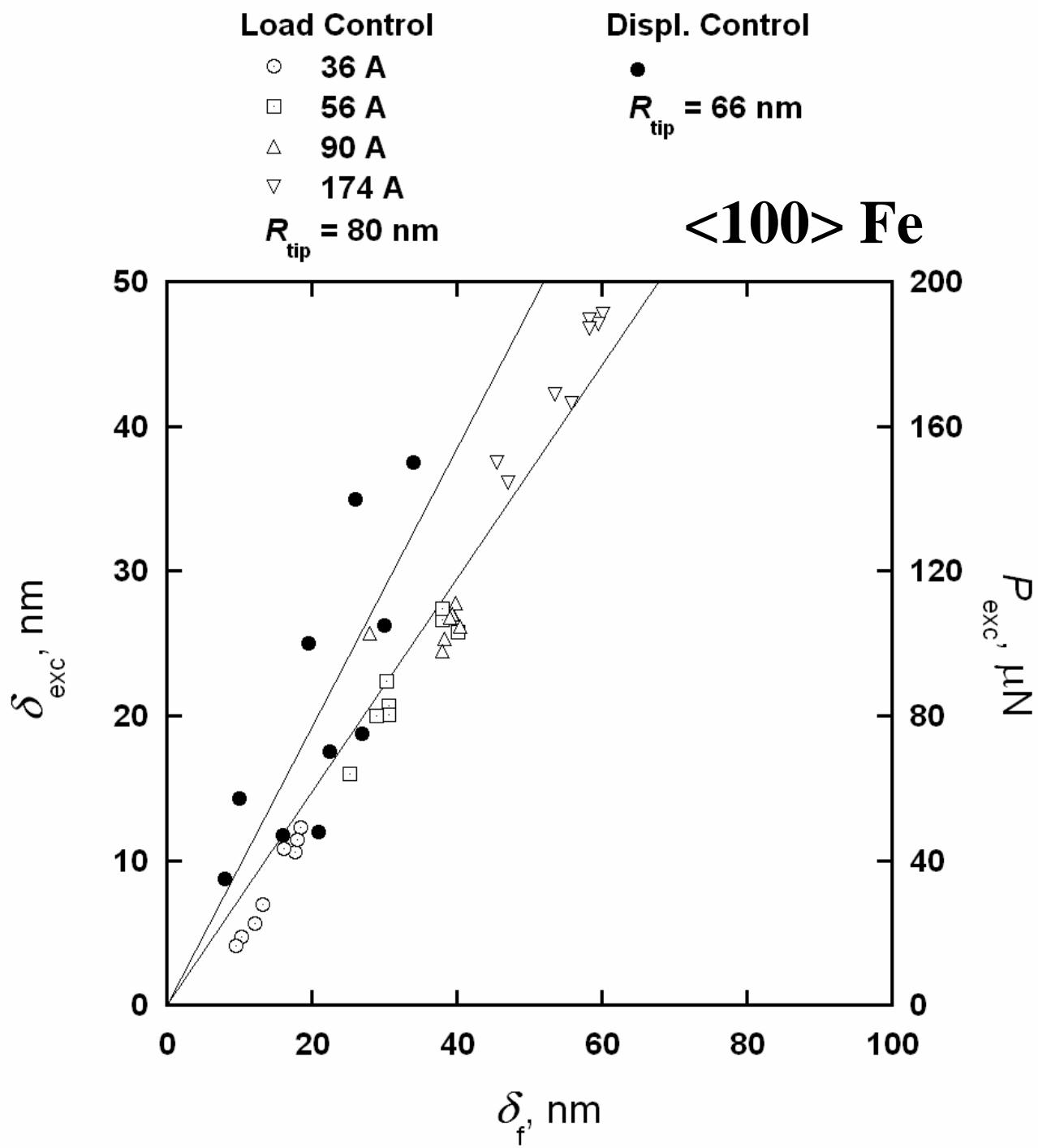
Staircase Yielding

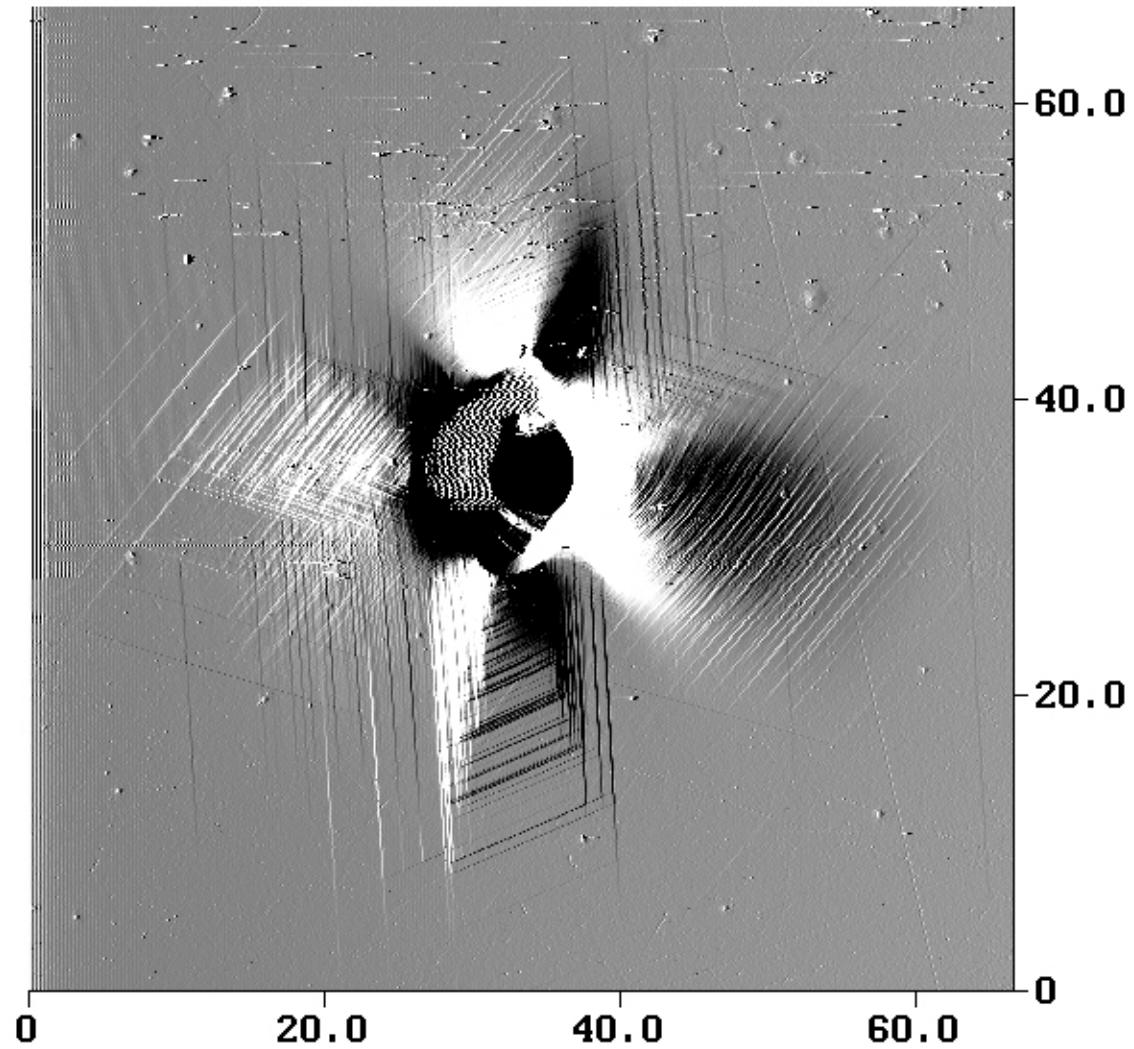
Bulk W



Thin film Al







courtesy K. Nibur, D. Bahr, Washington State

Energy Balance Approach to Yield Excursions

Released: $U_E = -P \left(\frac{a_1^2}{2R} - \frac{a_0^2}{2R} \right)$

Absorbed: $W_P = \frac{4}{9} \frac{Pa^2}{R}$

Absorbed: $\alpha \gamma_s A = \alpha \pi \frac{a^3}{R}$

$\rightarrow U_E + W_P + \alpha \gamma_s A = -P \delta_{exc} + \frac{4}{9} \frac{Pa^2}{R} + 2\sqrt{2} \pi \alpha \delta_f^{3/2} R^{1/2} \gamma_s$

$$\delta_{exc} = \frac{\text{const. } \alpha \gamma_s R^{1/2} \delta_f^{3/2}}{P}$$

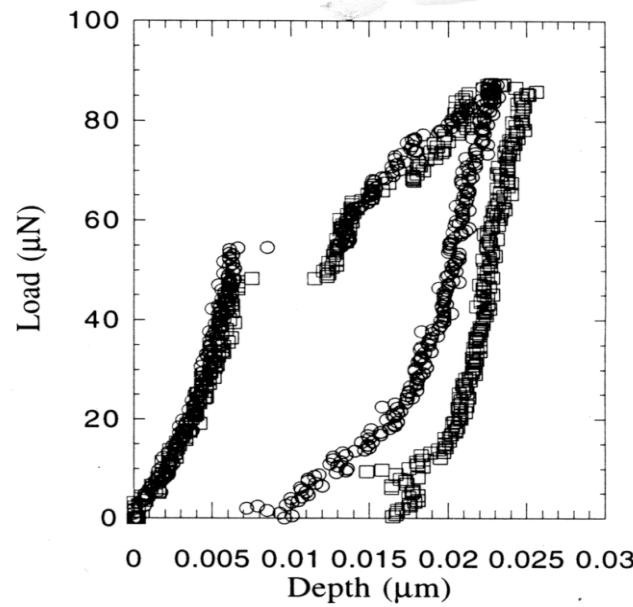
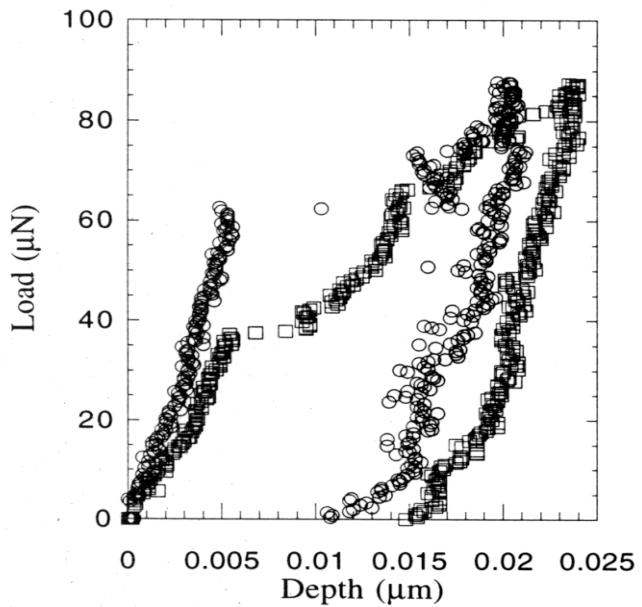
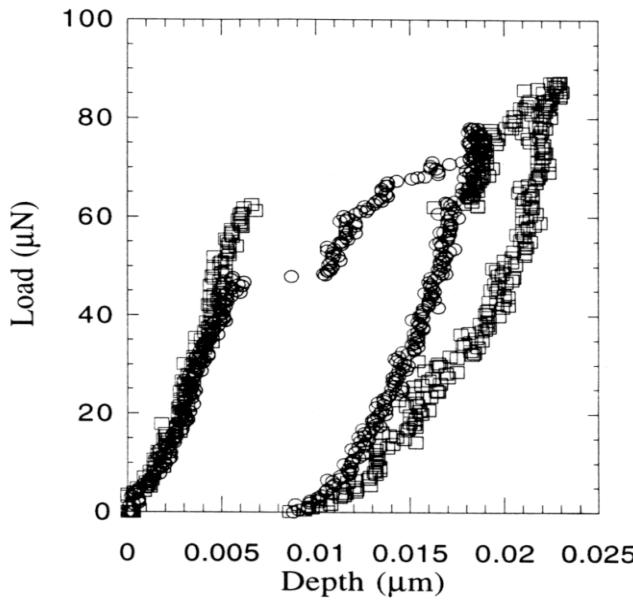
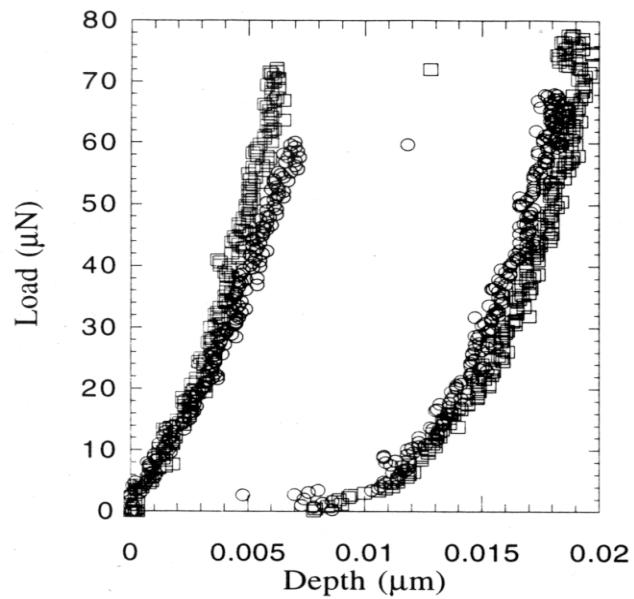
: a = contact radius
 R = tip radius
 P = load

: plastic energy from prismatic punched loops of radius a

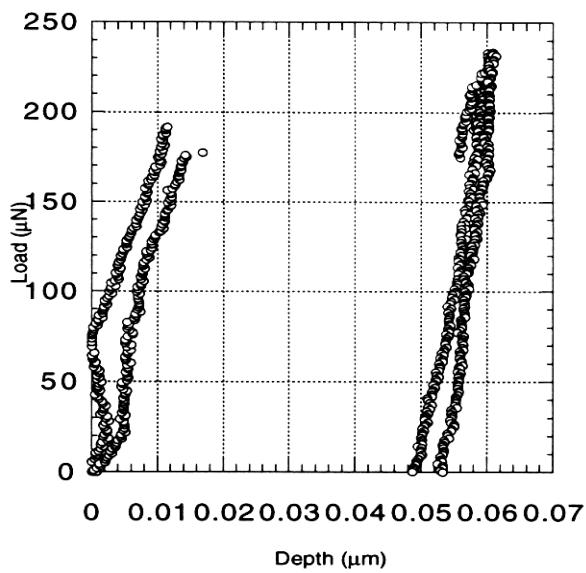
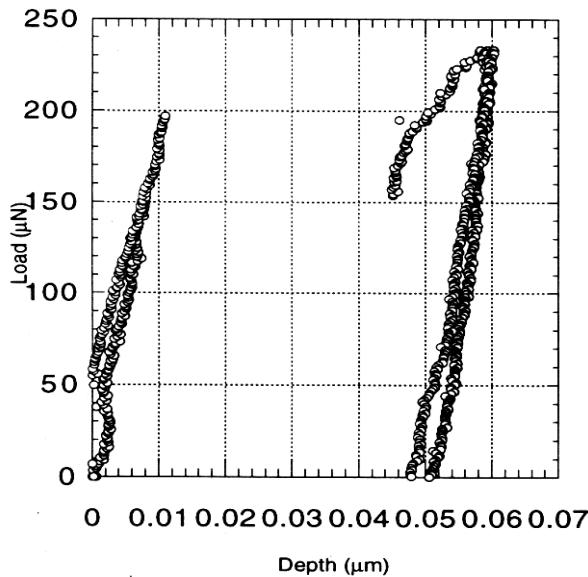
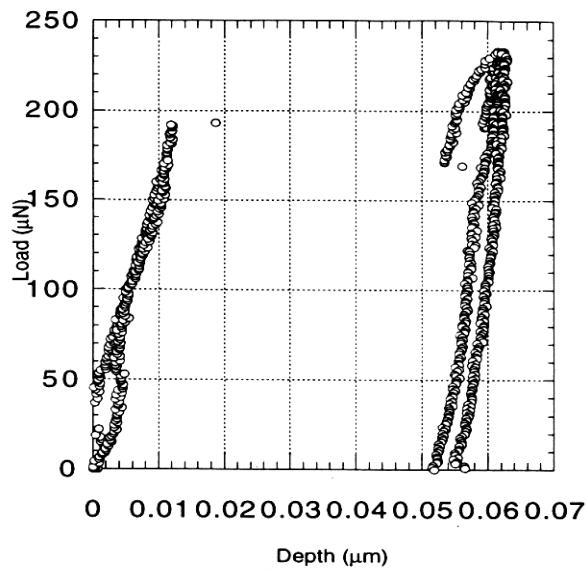
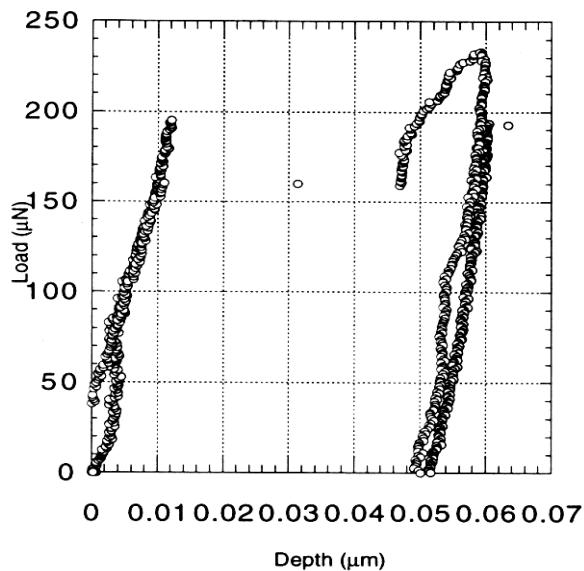
: energy from new area created
 γ_s = surface energy

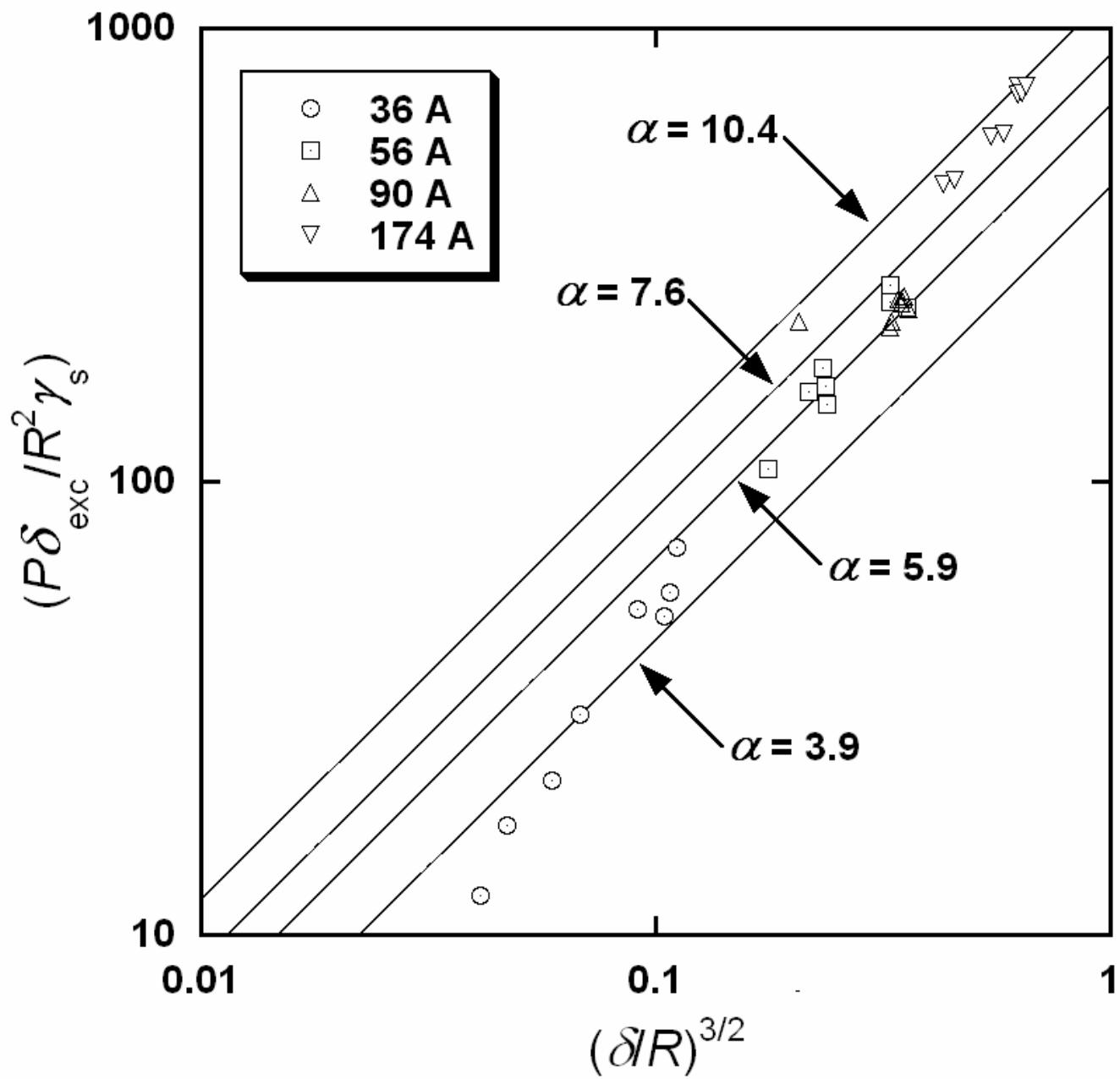
: δ_f = displacement at end of excursion
 α = mat'l specific constant

Fe 3% Si: 36 Å native oxide grown in air

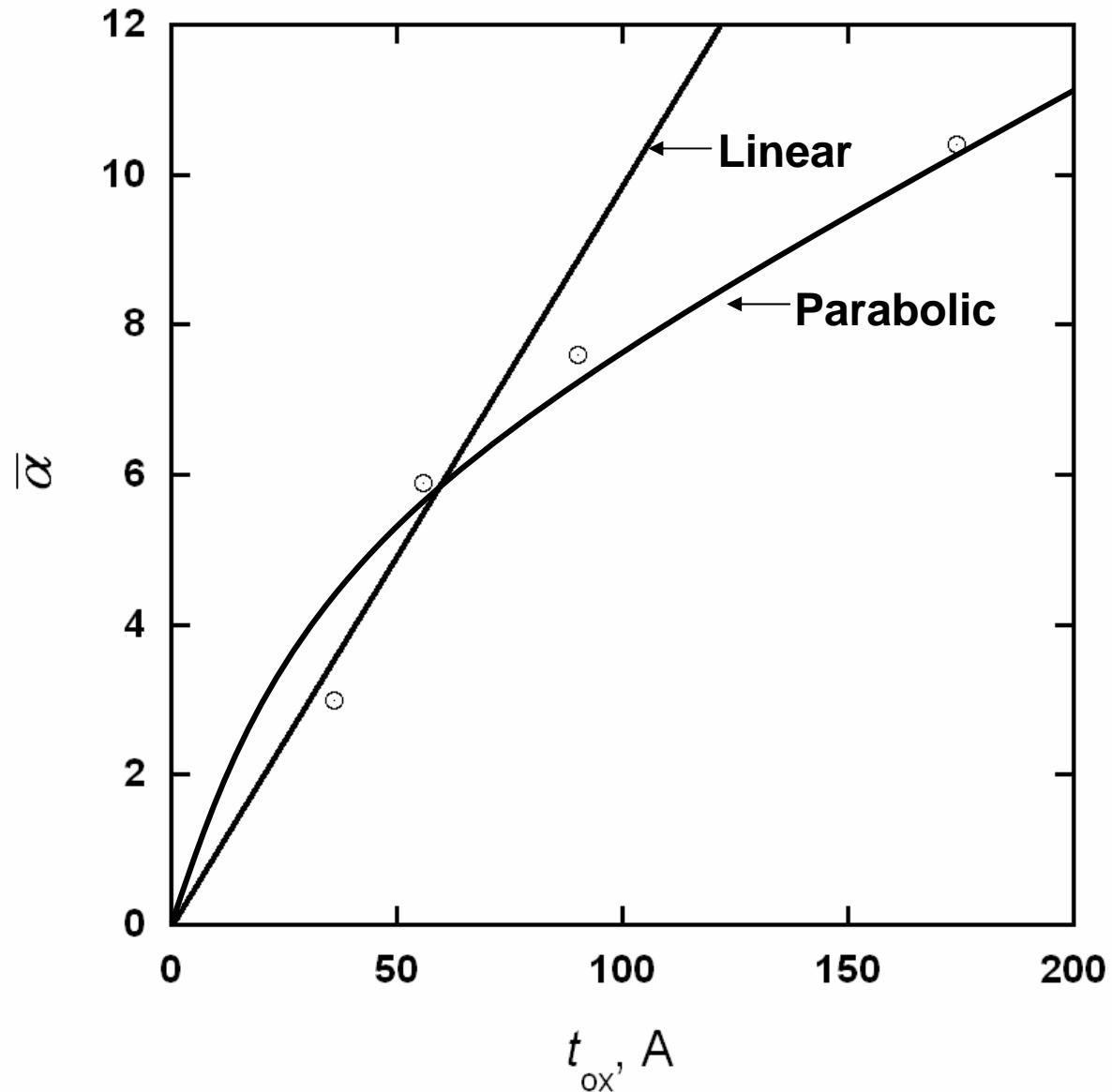


Fe 3% Si: 174 Å thermal oxide grown at 300 °C

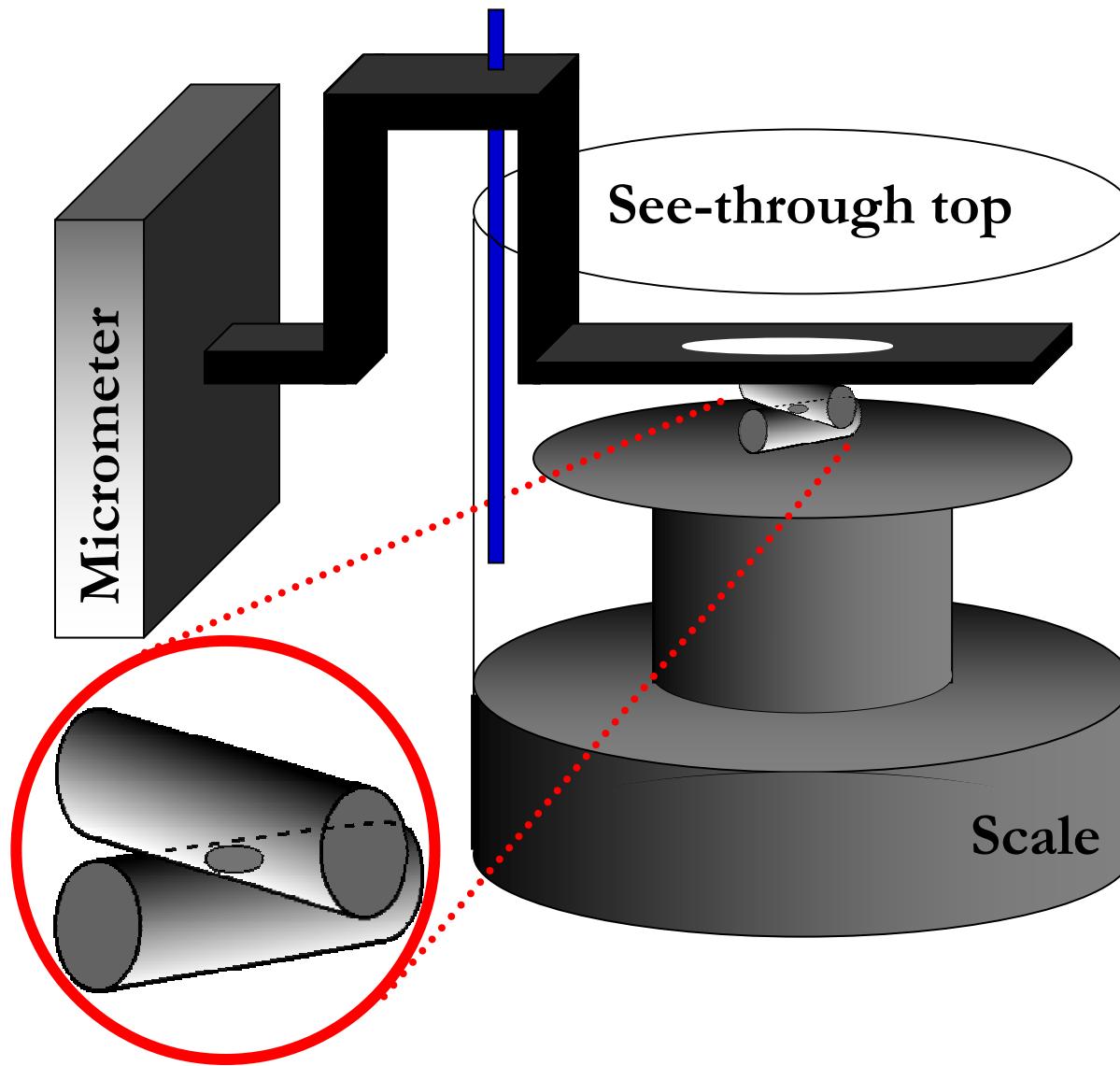




Oxide films on <100> Fe



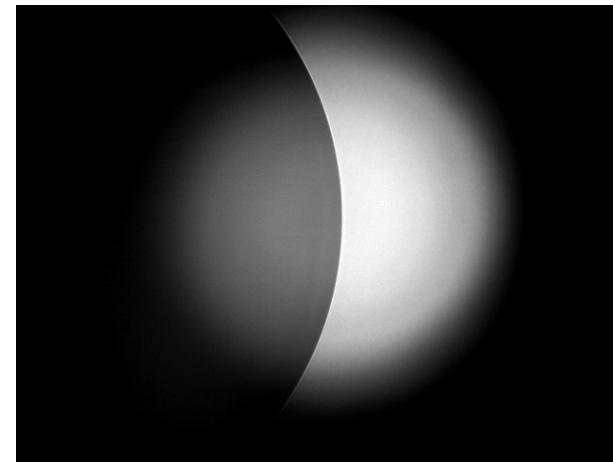
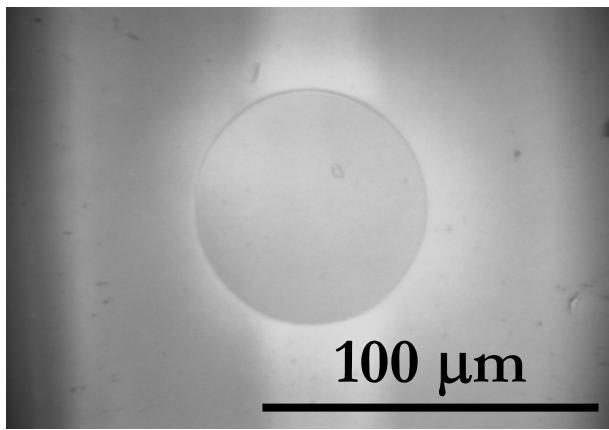
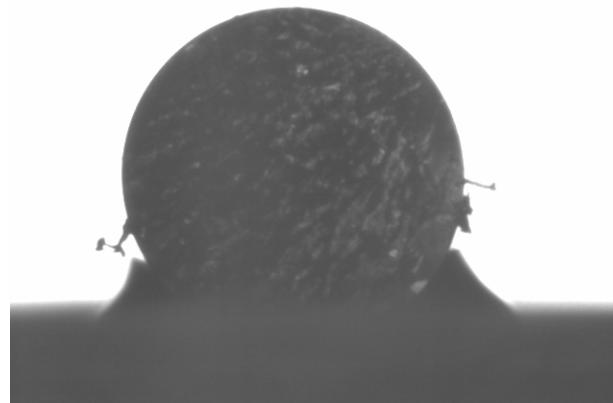
Normal Contact Adhesion Effects



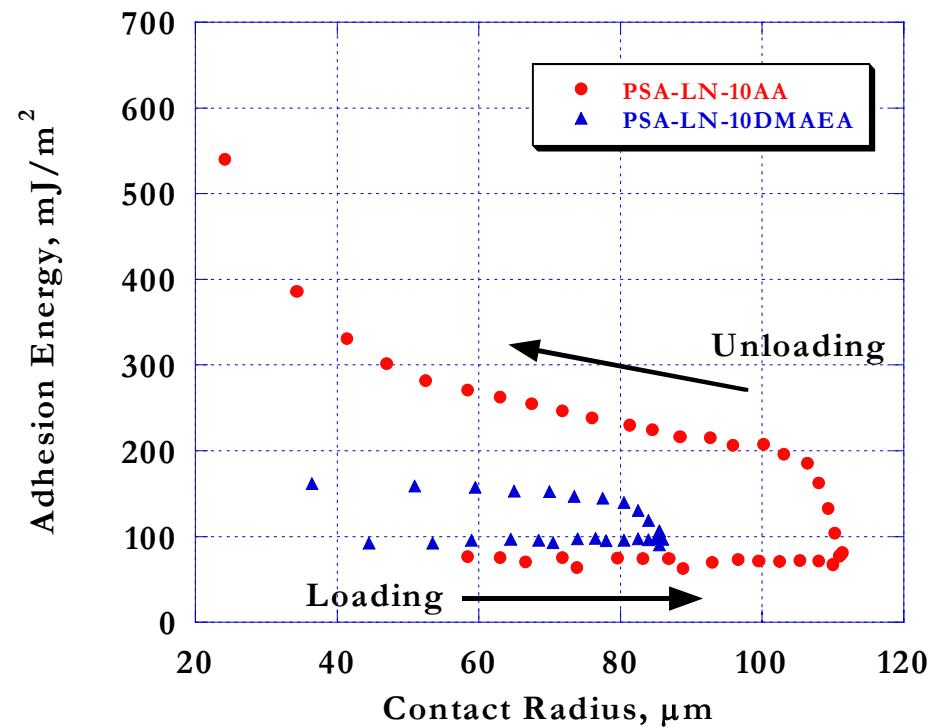
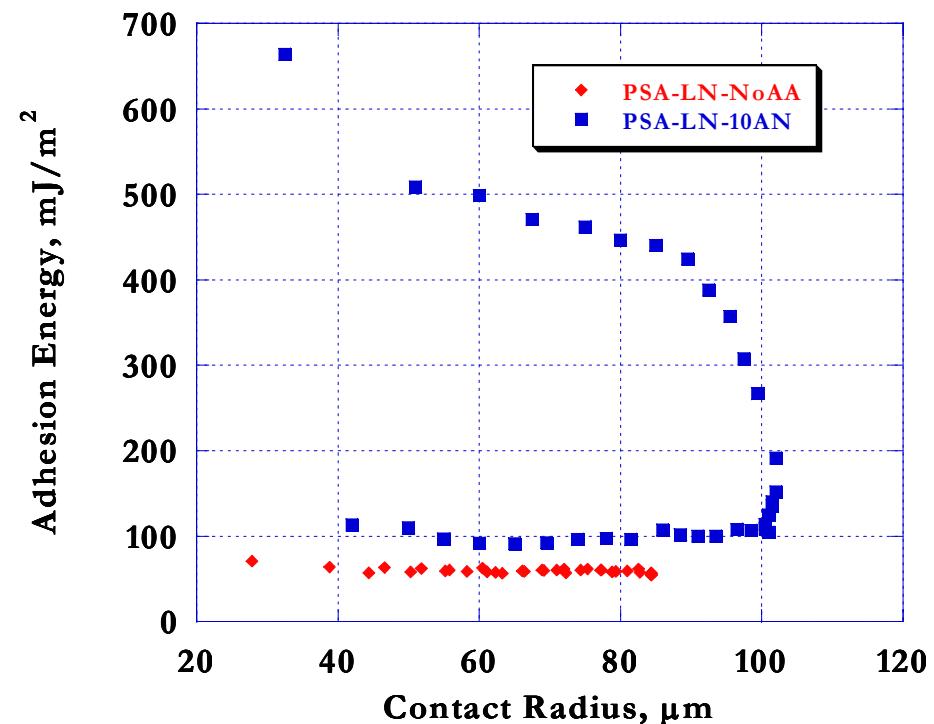
Optical Images



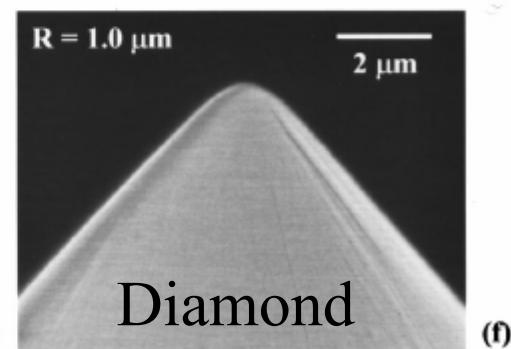
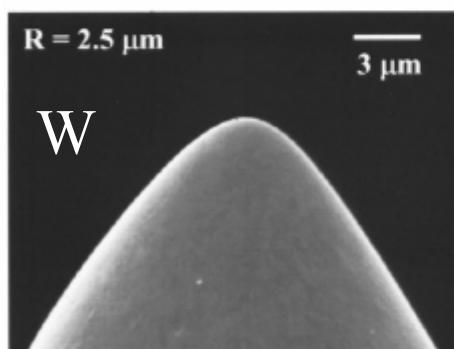
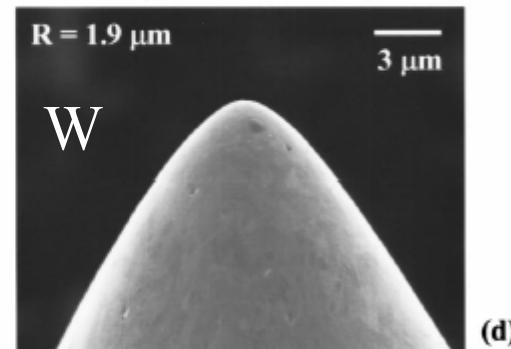
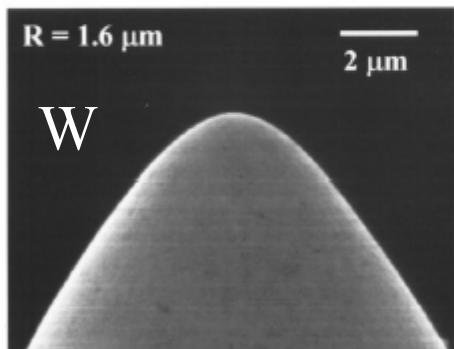
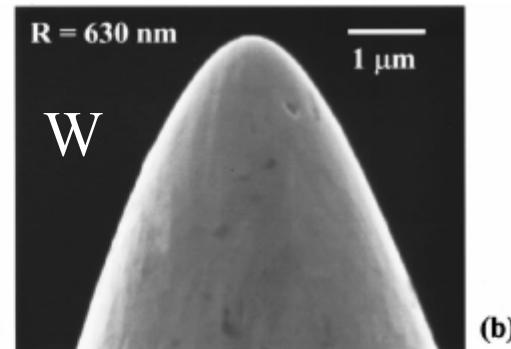
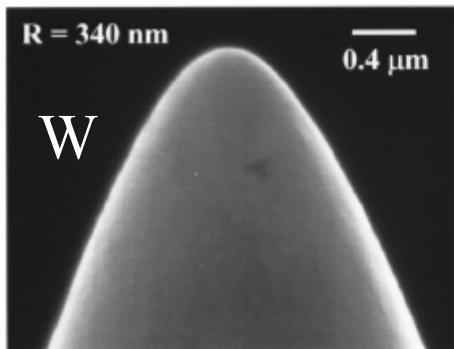
1000 μm



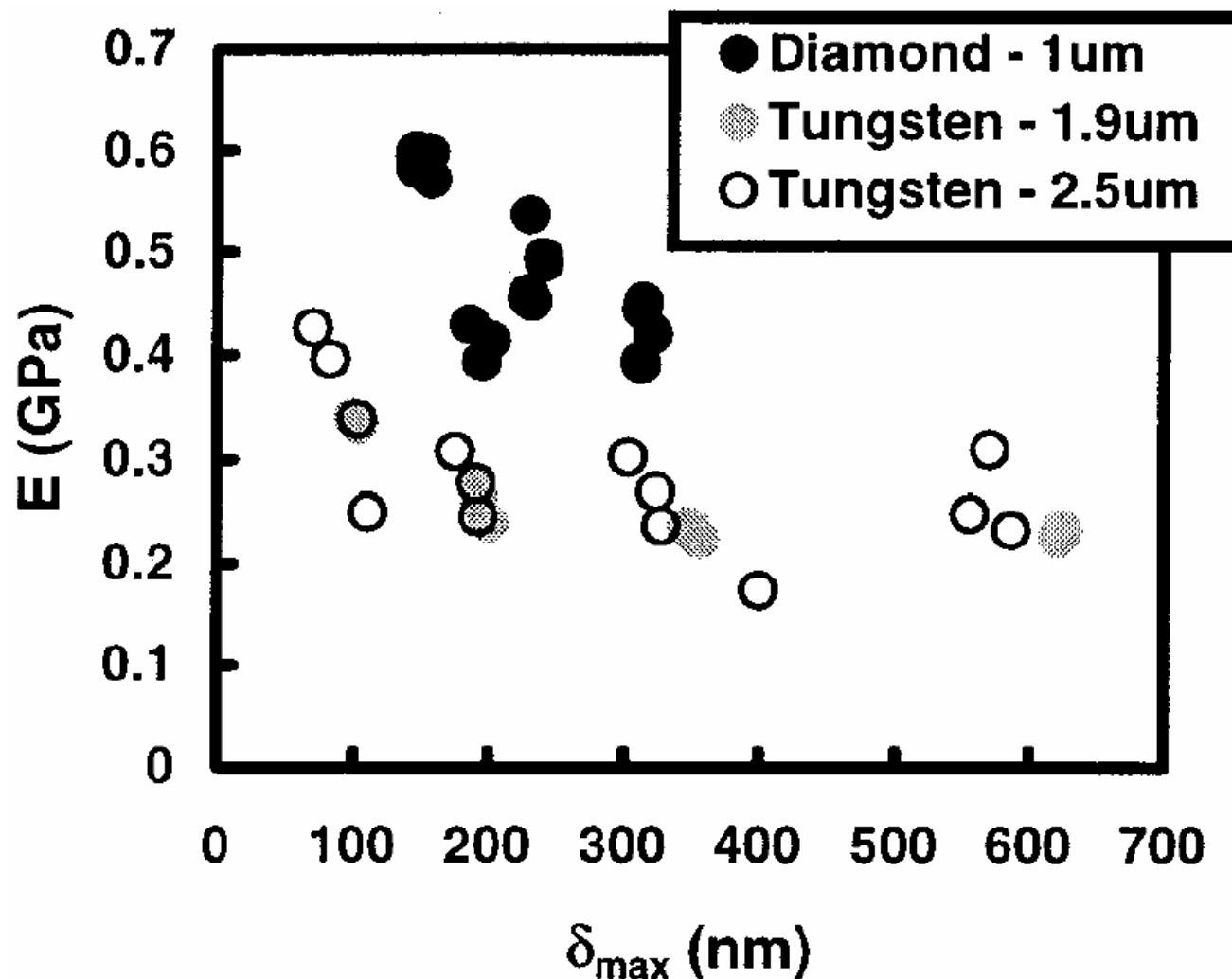
Adhesion Hystereses



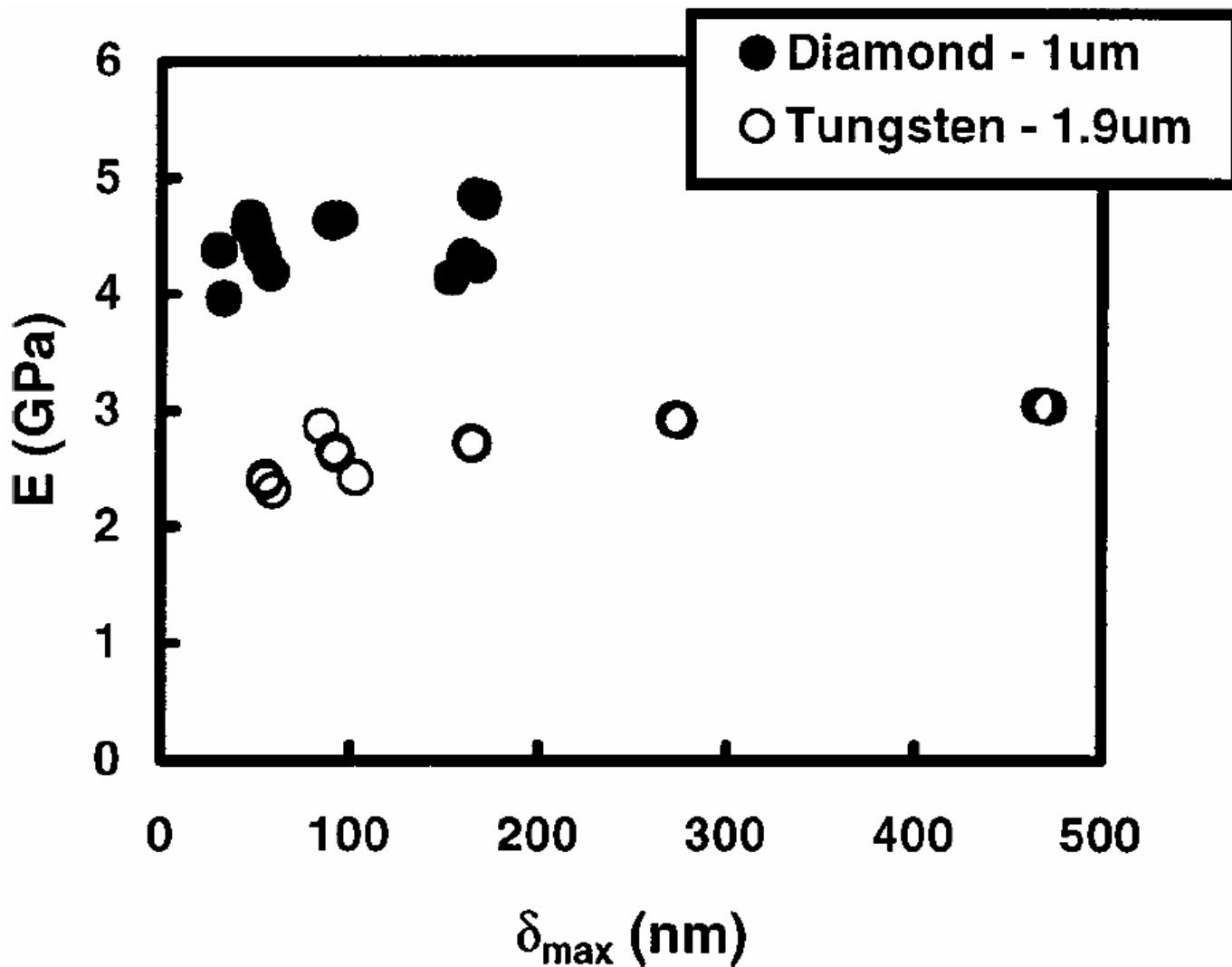
SEM of W indenter tips



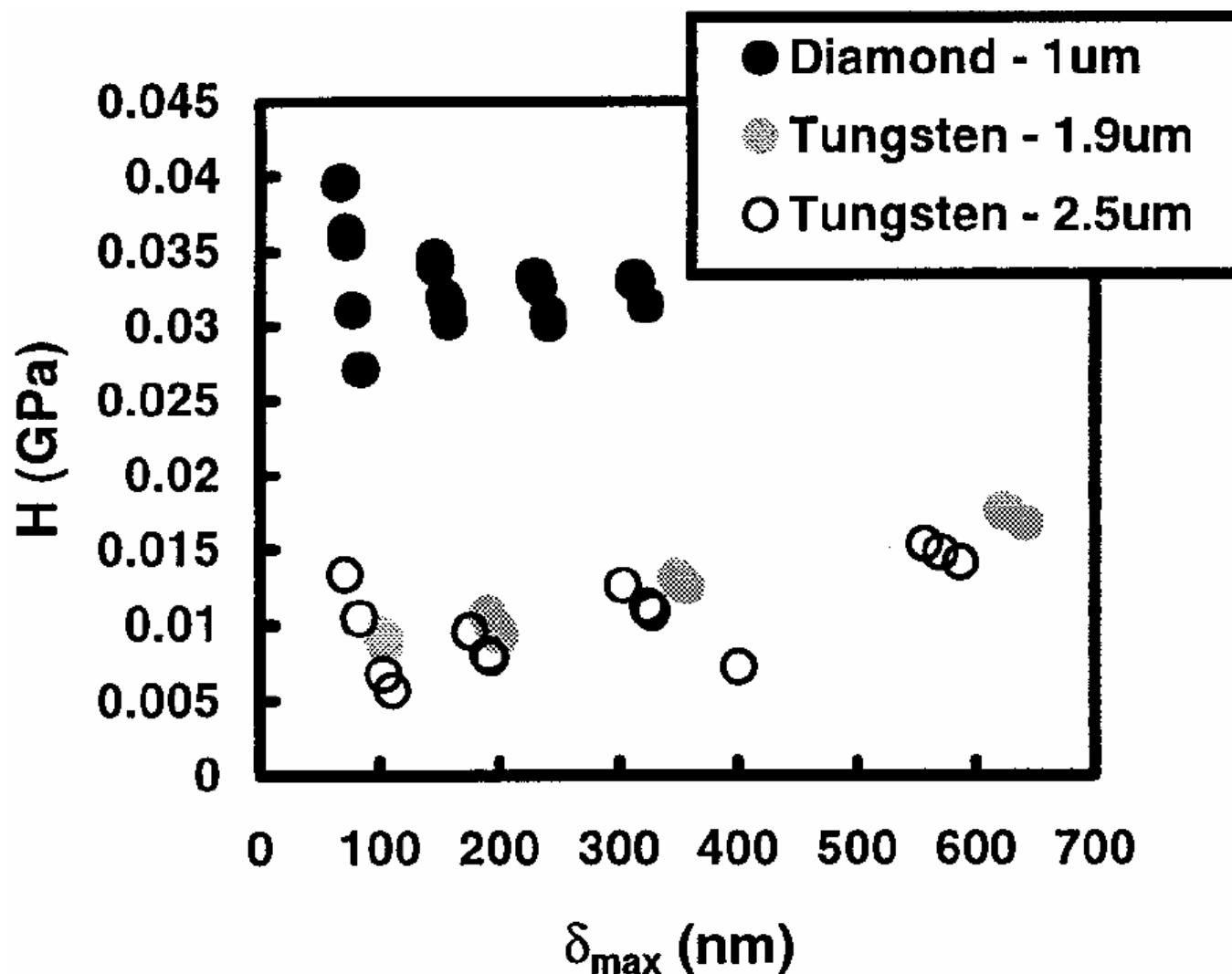
Indentation into bulk LDPE



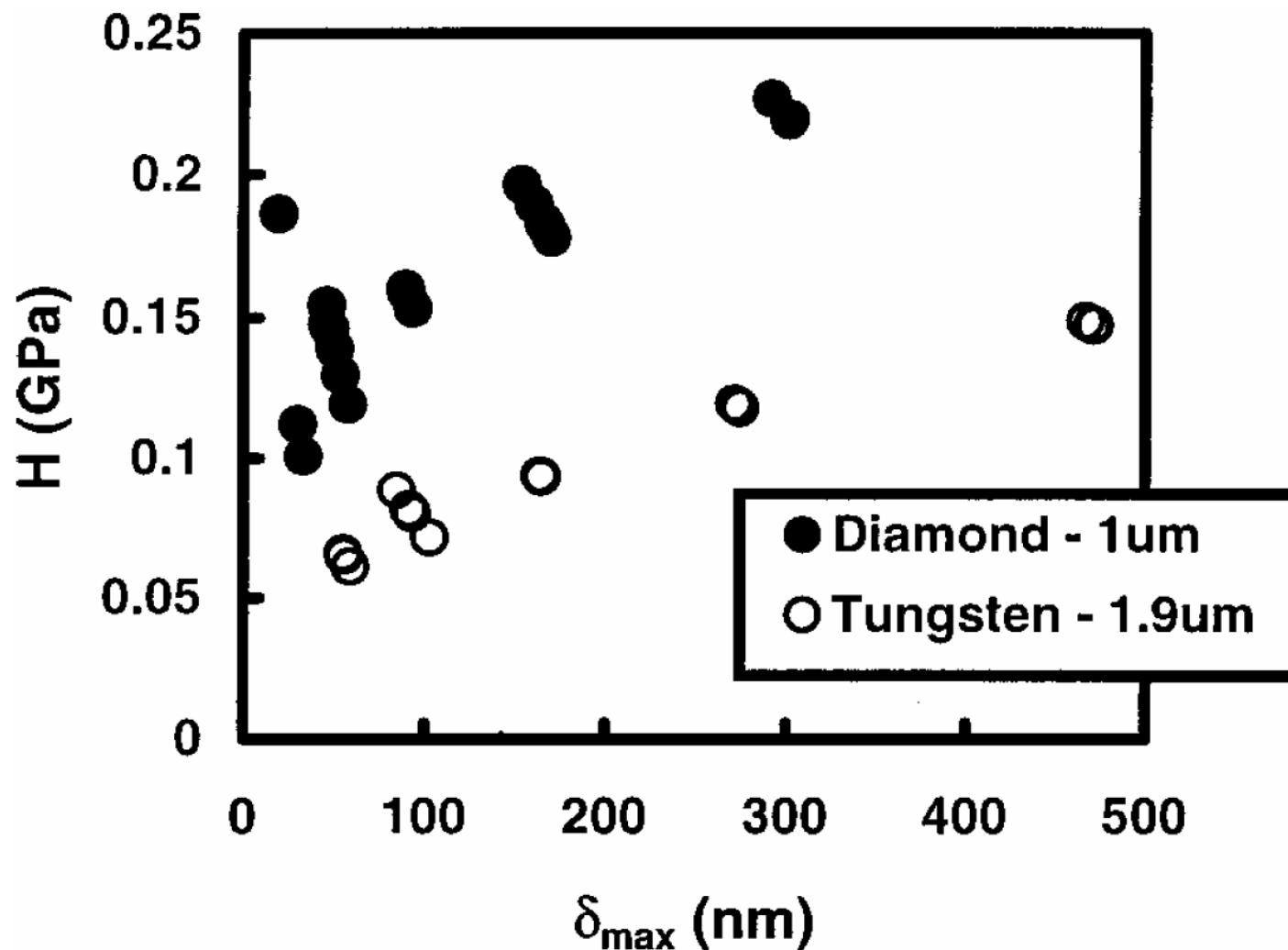
Indentation into bulk Polystyrene



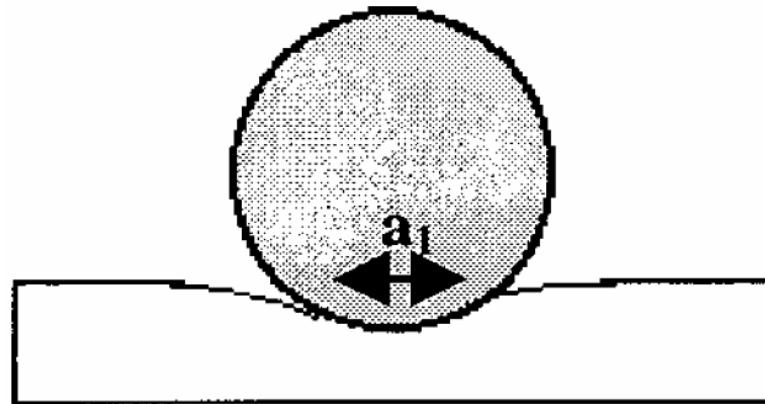
Indentation into bulk LDPE



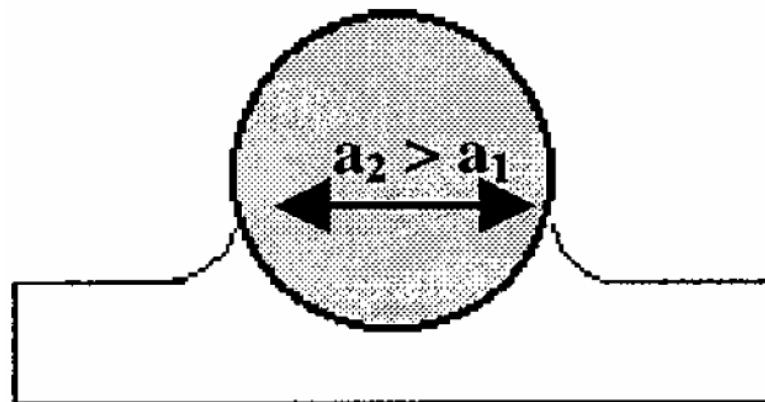
Indentation into bulk Polystyrene



Contact Size Variation

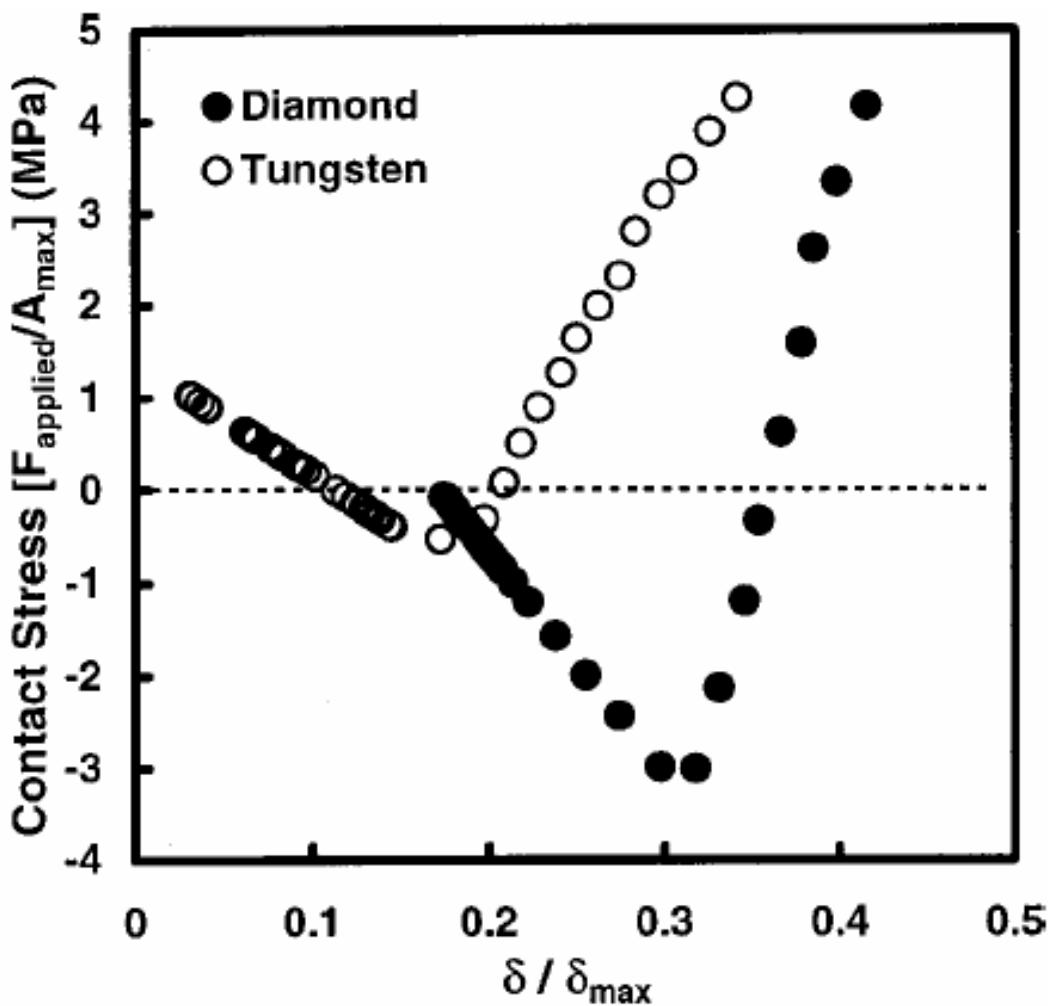


Poor Adhesion

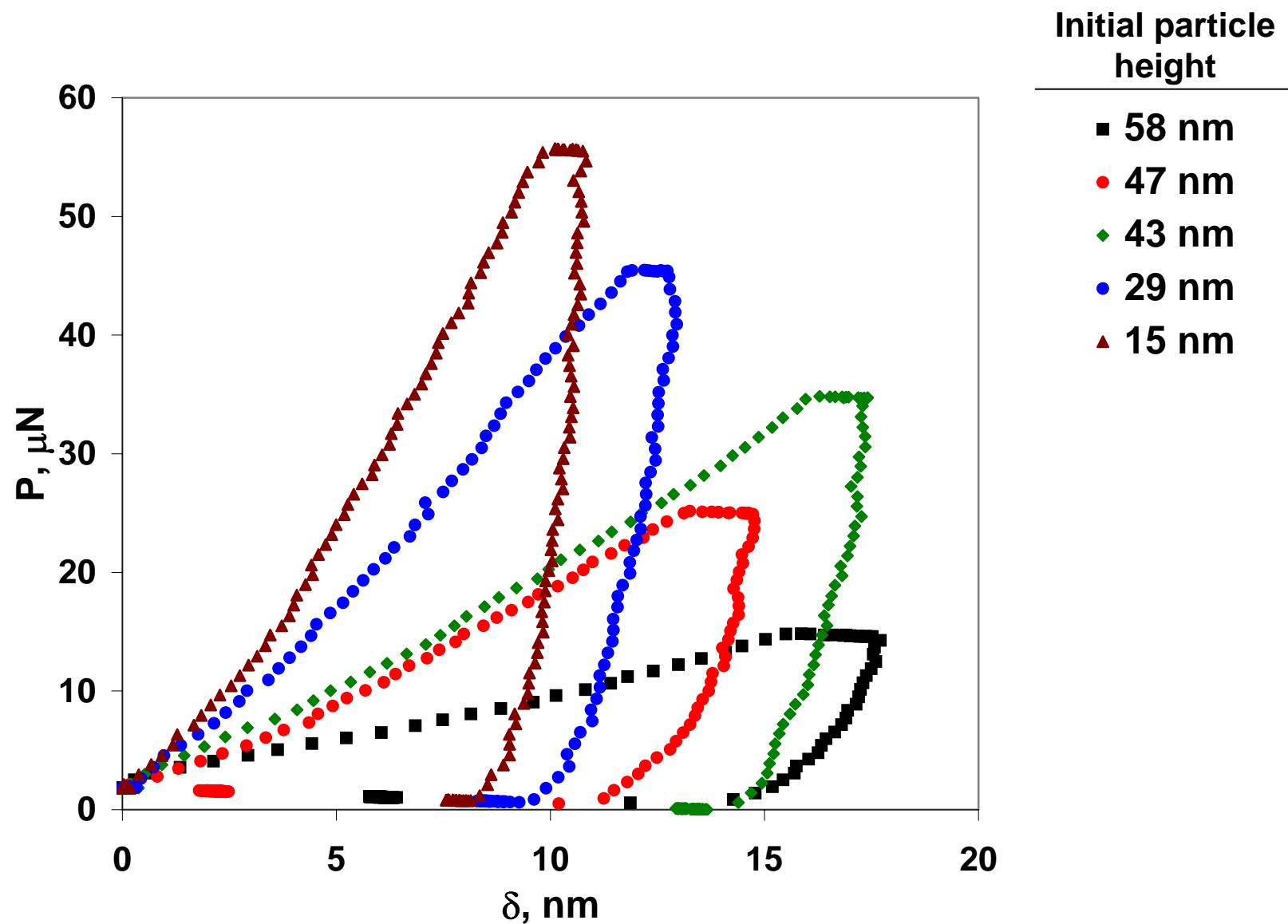


Good Adhesion

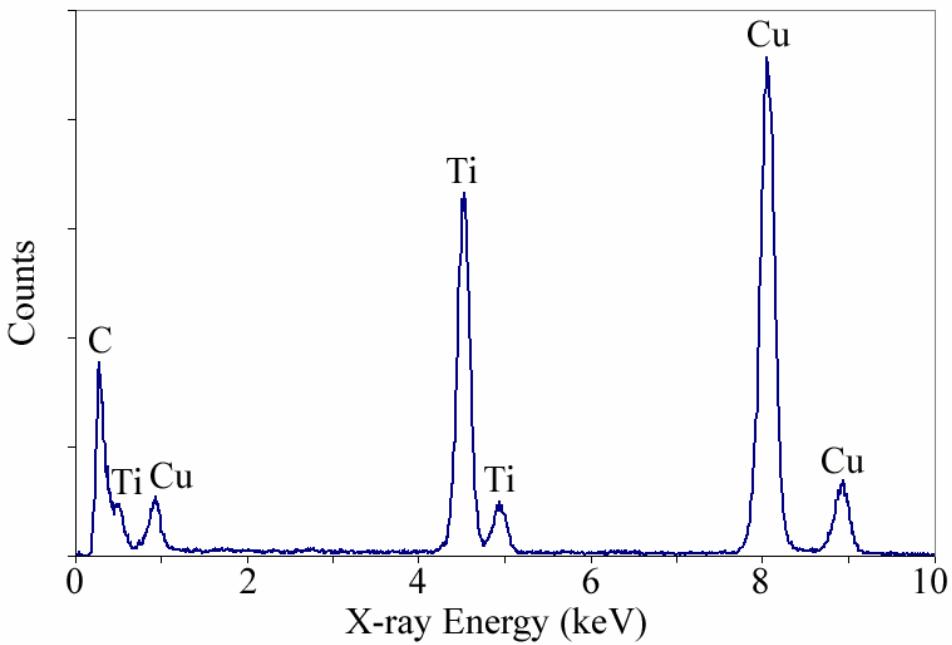
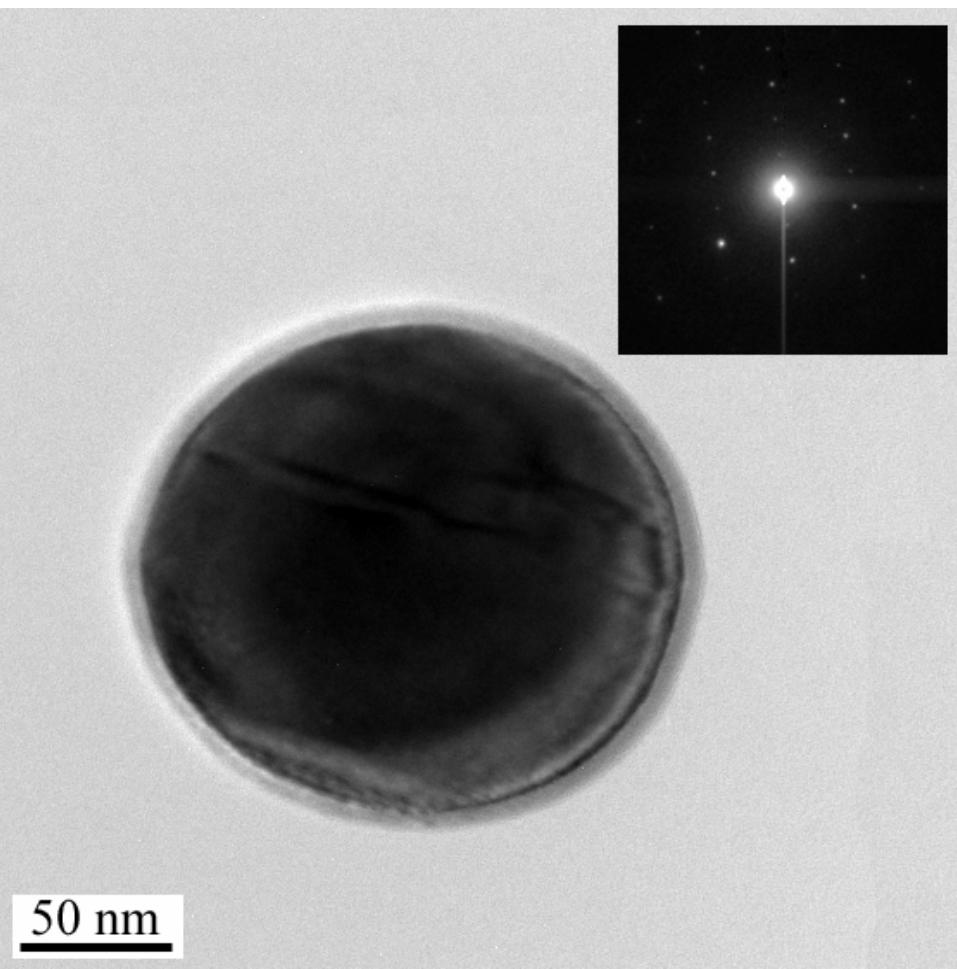
Pull-off from Indentation into Polystyrene



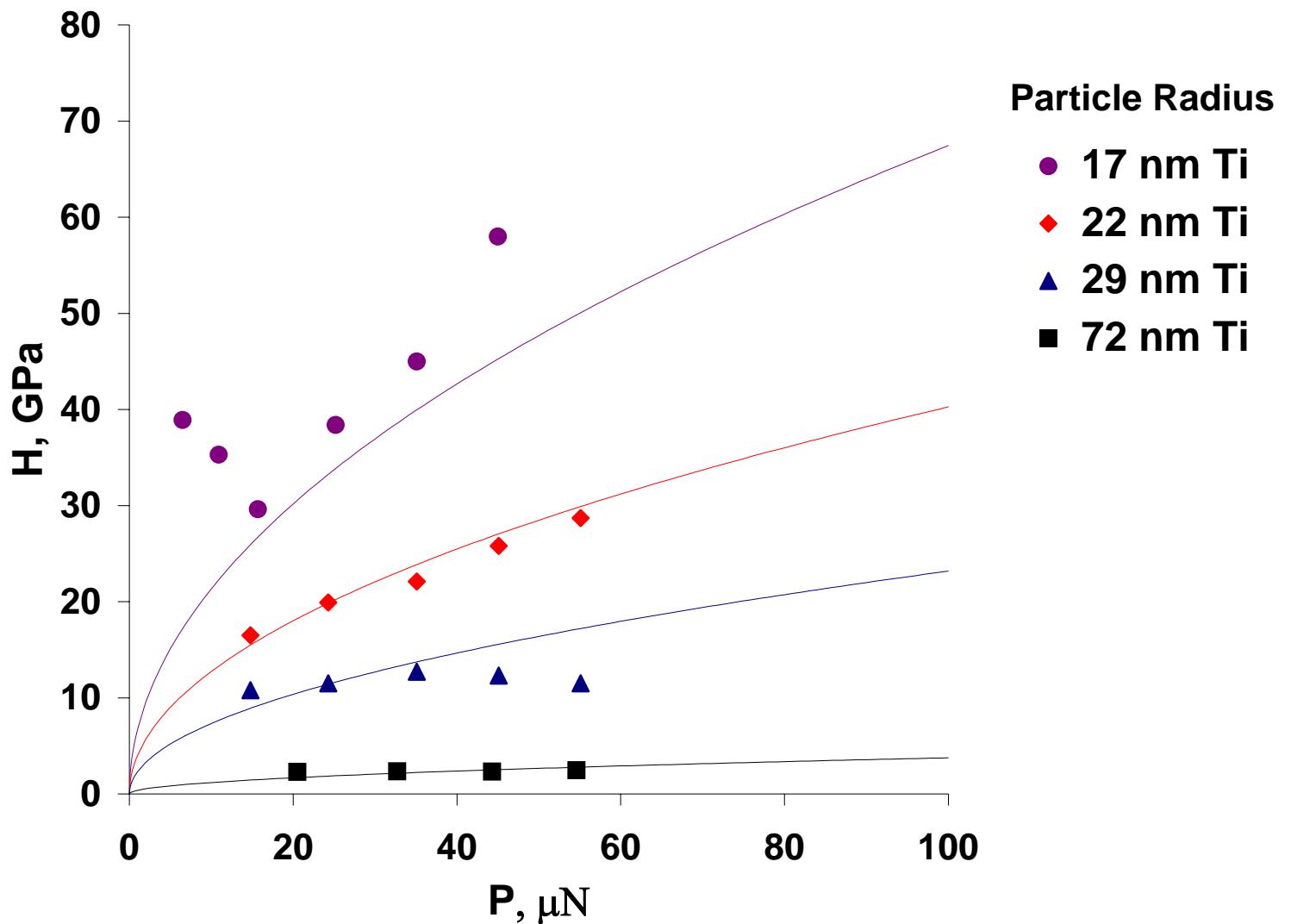
Ti Nanoparticle, $h = 58$ nm



TEM of Ti Nanoparticle



Ti Nanosphere Contact Pressure



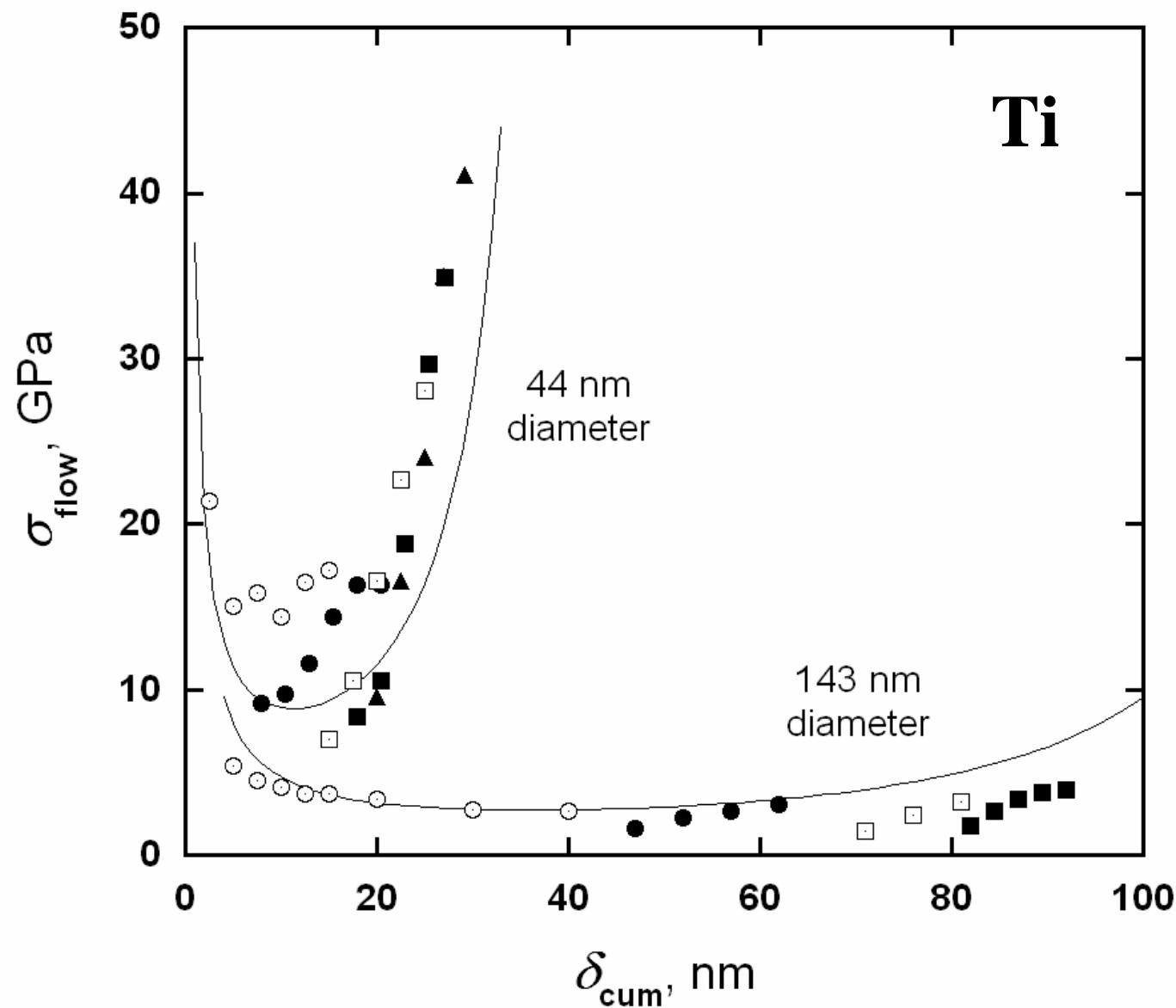
Hardness vs. Displacement

Using length scale $\frac{V}{S} = \frac{2r^3}{3a^2}$, one can show

$$H = \frac{2}{3} \sigma_{ys} \left(\frac{r}{\delta} \right) + \frac{3\mu}{2\pi(1-\nu)} \left(\frac{\delta}{r} \right)^2$$

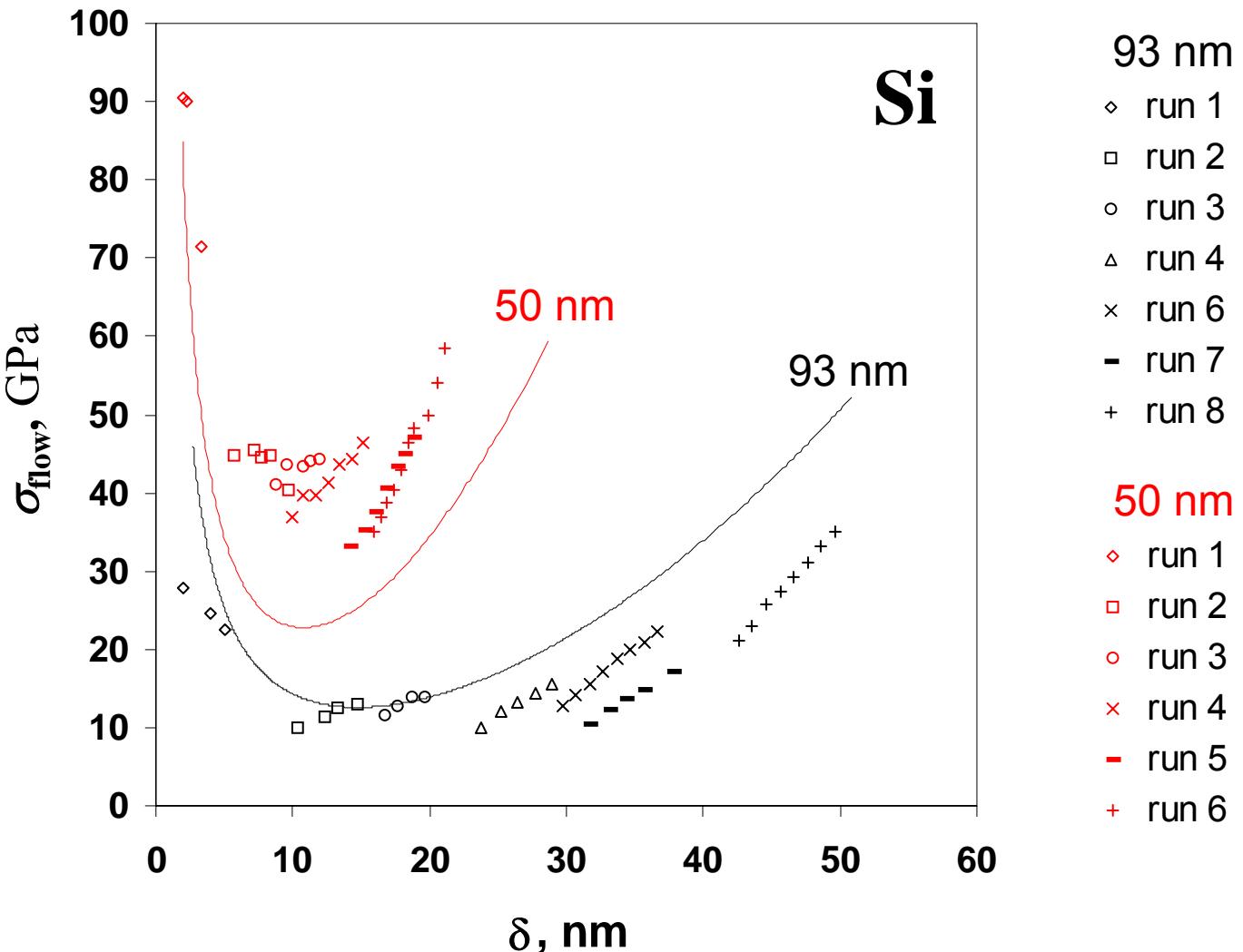
Surface Dominant Plastic Pile-up Dominant

σ_{ys} is the only variable which can be back-calculated from the minima.



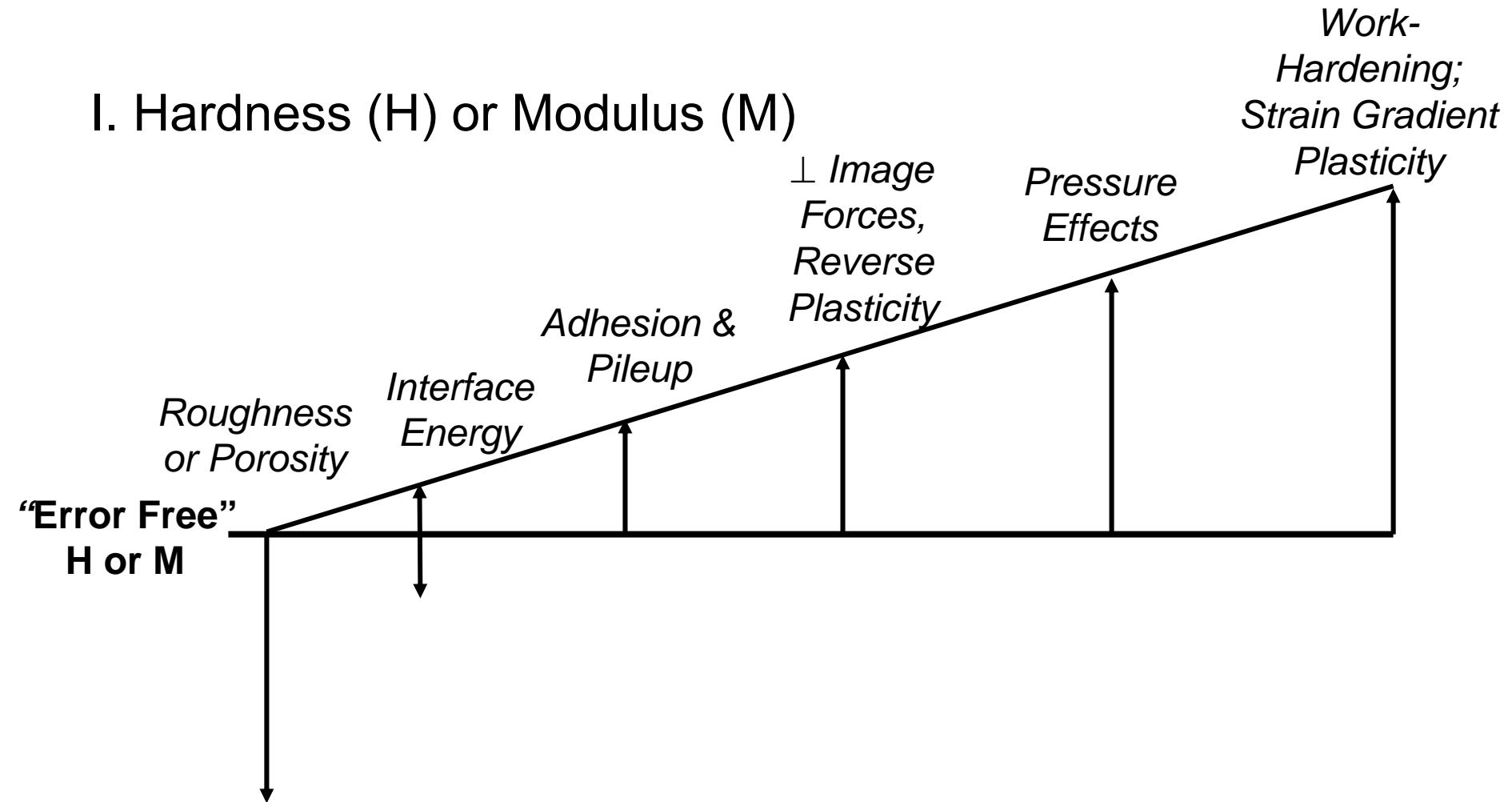
- Simple Superposition :

$$\sigma_{\text{flow}} = \frac{2}{3} \sigma_{\text{ys}} \left(\frac{r}{\delta} \right) + \frac{3\mu}{2\pi(1-\nu)} \left(\frac{\delta}{r} \right)^2$$



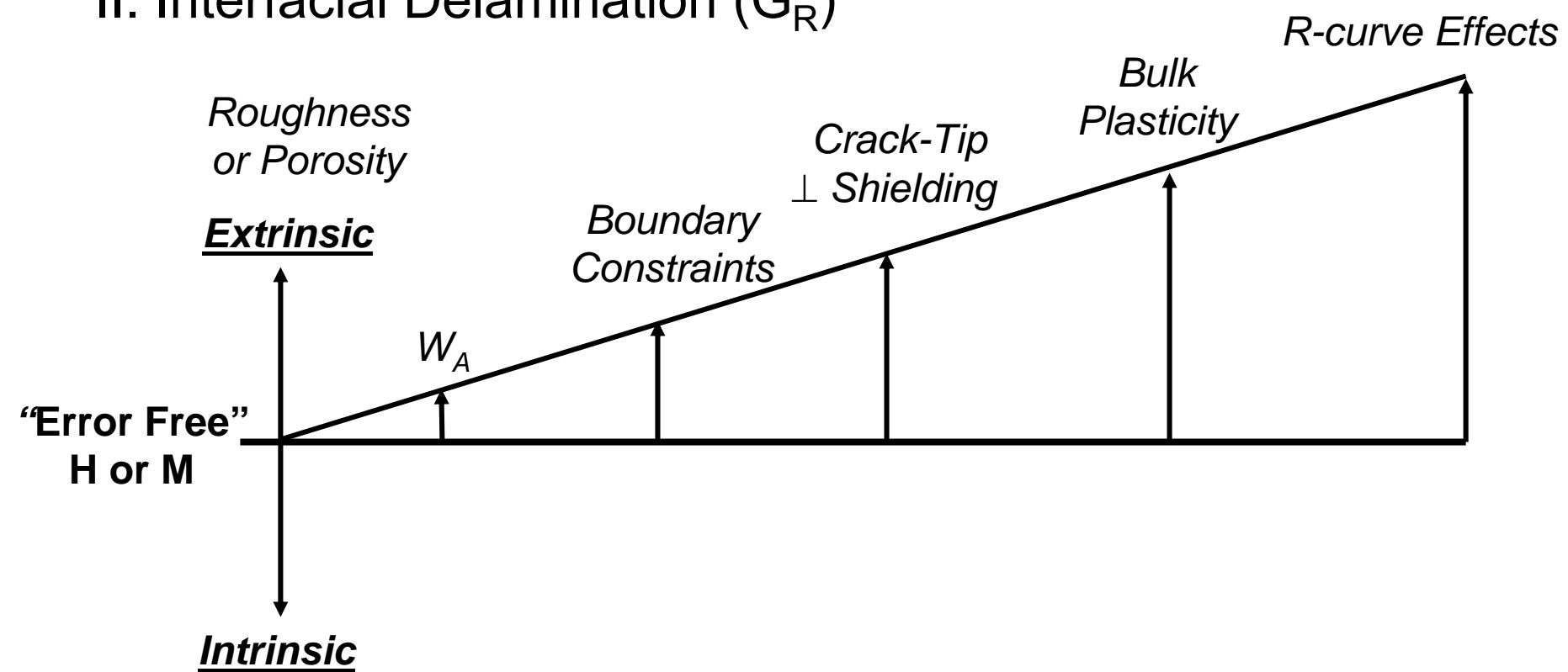
Measurement Road Maps: Nanoindentation

I. Hardness (H) or Modulus (M)

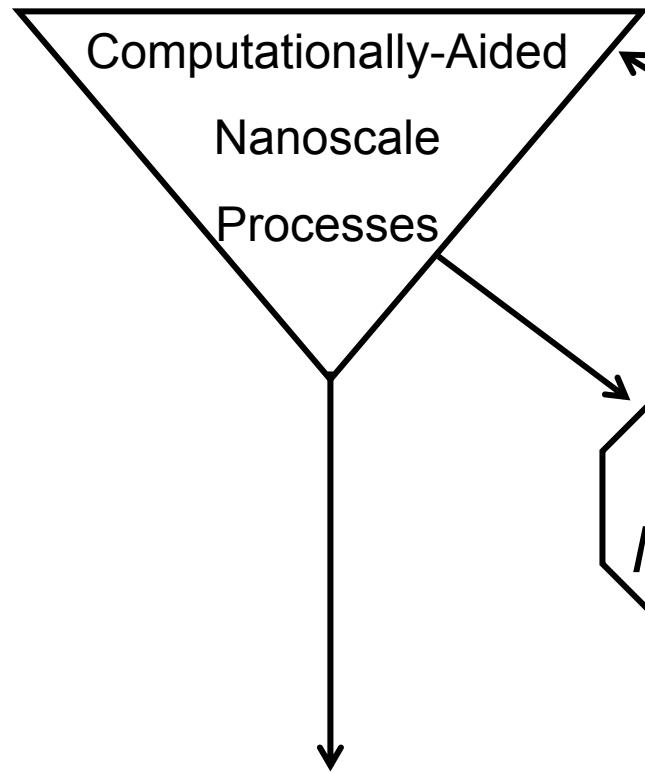


Measurement Road Maps: Nanoindentation

II. Interfacial Delamination (G_R)

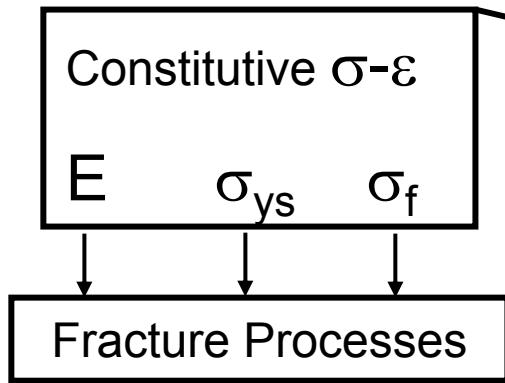
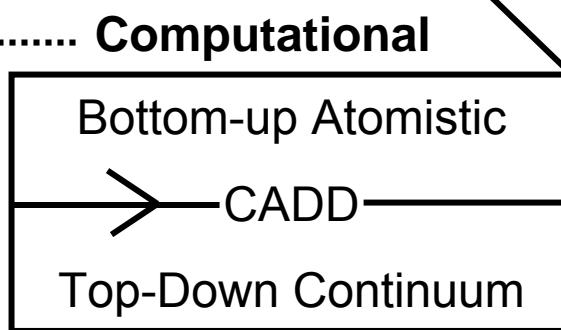


Manufacturing

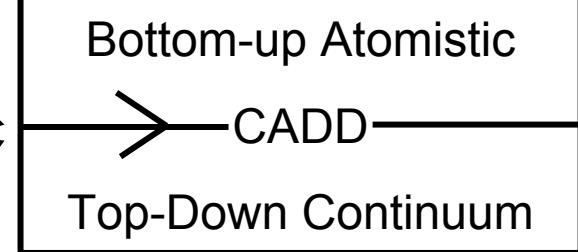


Compatibility Issues

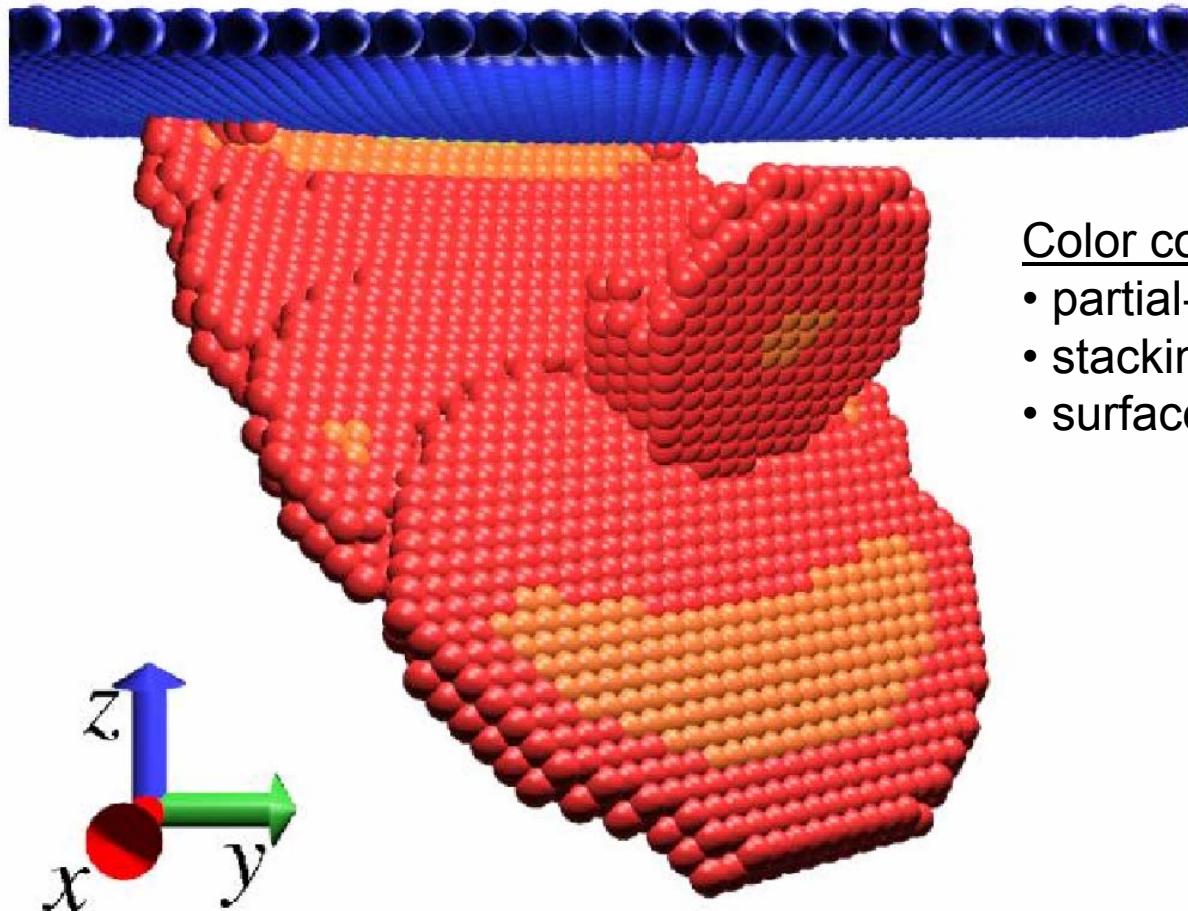
- Electronic
- Magnetic
- Optical
- Bio



Road Maps

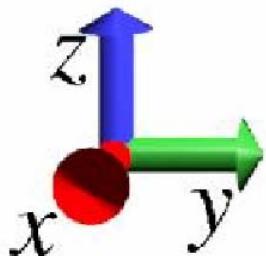


Dislocation pattern resulting from indentation into (001) gold



Color coding

- partial-dislocation core atoms (red)
- stacking-fault atoms (yellow)
- surface atoms (blue)



Si Nanospheres: Variation of Oxide Thickness

